### Scilab Textbook Companion for Electronic Devices And Circuits by B. Kumar And S. B. Jain<sup>1</sup>

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## **Book Description**

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Scilab numbering policy used in this document and the relation to the above book.

Exa Example (Solved example)

Eqn Equation (Particular equation of the above book)

**AP** Appendix to Example(Scilab Code that is an Appednix to a particular Example of the above book)

For example, Exa 3.51 means solved example 3.51 of this book. Sec 2.3 means a scilab code whose theory is explained in Section 2.3 of the book.

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### Chapter 1

### **Semiconductor Physics**

Scilab code Exa 1.1 Electron concentration

1 // Example 1.1: Electron concentration 2 clc, clear 3 V=0.1; // Voltage in volts 4 I=5e-3; // Current in ampere 5 l\_a=7e8; // Length to cross-sectional area ratio in metre inverse 6 mu=0.05; // Electron mobility in metre square per volt second 7 q=1.6e-19; // Charge on an electron in coulombs 8 n=(l\_a\*I)/(V\*q\*mu); // Electron concentration in inverse metres cube 9 n=n\*1e-6; // Electron concentration in inverse centimetres cube 10 disp(n,"Electon concentration (cm^-3) = ");

#### Scilab code Exa 1.2 Intrinsic Silicon

1 // Example 1.2: Electric field intensity, Voltage

```
2 clc, clear
3 l=3e-3; // Length of the bar in metres
4 a=50*10*1e-12; // Cross-sectional area in metres
square
5 I=2e-6; // Current in amperes
6 rho=2.3e3; // Resistivity in ohm metres
7 E=I*rho/a; // Electric field intensity in volt per
metres
8 V=E*1; // Voltage across the bar in volt
9 disp(E,"Electic field intensity (V/m) = ");
10 disp(V,"Voltage across the bar (V) = ");
```

Scilab code Exa 1.3 Extrinsic n type Silicon

1 // Example 1.3: Electron concentration, Hole concentration, Conductivity, Voltage 2 clc, clear 3 1=3e-3; // Length on Si sample in metres 4 a=5e-9; // Cross-sectional area of Si sample in metres square 5 ND=5e20; // Donor concentration in inverse metres cube 6 I=2e-6; // Current flowing through the bar in amperes ni=1.45e16; // Intrinsic carrier concentration in 7 inverse metres cube 8 mu\_n=0.15; // Mobility of electrons in metres square per volt second 9 q=1.6e-19; // Charge on an electron in coulombs 10 n=ND; // Electron concentration in inverse metres cube 11 p=ni\*ni/n; // Hole concentration in inverse metres cube 12 sigma=q\*n\*mu\_n; // Conductivity of Si sample in inverse ohm metres

- 13 V=(I\*1)/(a\*sigma); // Voltage across the bar in volts
- 14 n=n\*1e-6; // Electron concentration in inverese centimetres cube

- 17 disp(n," Electron concentration  $(cm^{-3}) = "$ );
- 18 disp(p,"Hole concentration  $(cm^{-3}) = "$ );
- 19 disp(sigma, "Conductivity of Si sample (ohm^-1 cm^-1) = ");
- 20 disp(V,"Voltage across the bar (V) = ");

Scilab code Exa 1.4 Contact difference of potential

```
1 // Example 1.4: Contact difference of potential
2 clc, clear
3 N=5e22; // Number of acceptor or donor atoms per
metres cube of step graded p-n junction
4 ni=1.45e16; // Intrinsic carrier concentration in
inverse metres cube
5 VT=25e-3; // Voltage equivalent to temperatue at
room temperature in volts
6 Vo=VT*log(N^2/ni^2); // Contact difference of
potential in volts
7 Vo=Vo*1e3; // Contact difference of potential in
milivolts
```

8 disp(Vo, "Contact difference of potential (mV) = ");

#### Scilab code Exa 1.7 Potential barrier

1 // Example 1.7: Potential barrier

2 clc, clear

- 3 rho\_p=0.05; // Resistivity of p side of step-graded junction in ohm metres
- 4 rho\_n=0.025; // Resistivity of n side of step-graded junction in ohm metres
- 5 mu\_p=475e-4; // Mobility of holes in metres square per volt second
- 6 mu\_n=1500e-4; // Mobility of holes in metres square per volt second
- 7 ni=1.45e16; // Intrinsic carrier concentration in atoms per metres cube
- 8 q=1.6e-19; // Charge on an electron in coulombs
- 9 VT=25e-3; // Voltage equivalent to temperatue at room temperature in volts
- 10 NA=1/(q\*mu\_p\*rho\_p); // Acceptor concentration in atoms per metres cube
- 12 Vo=VT\*log(NA\*ND/ni^2); // Contact difference of potential in volts
- 13 Vo=Vo\*1e3; // Contact difference of potential in milivolts
- 14 disp(Vo, "Contact difference of potential (mV) = ");

### Chapter 2

### The p n Junction Diode

Scilab code Exa 2.1 Ideal diodes

```
1 // Example 2.1: (a) I,Vo
2 / /
                   (b) I, Vo
3 clc, clear
4
5 disp("Part (a)");
6 // Applying Thevnin's theorem at XX', in Fig. 2.5(a)
7 Vth=15*20e3/(10e3+20e3); // Thevnin equivalent
     voltage in volts
8 Zth=10e3*20e3/(10e3+20e3); // Thevnin equivalent
     resistance in ohms
9 // From the figure 2.5(c)
10 I=Vth/(Zth+20e3); // Labelled current in amperes
11 Vo=I*20e3; // Labelled voltage in volts
12 I=I*1e3; // Labelled current in miliamperes
13 disp(I,"Labelled current I (mA) = ");
14 disp(Vo, "Labelled voltage Vo (V) = ");
15
16 disp("Part (b)");
17 // Applying Thevnin's theorem at XX' and YY', in Fig
     . 2.5(b)
18 Vth1=15*10e3/(10e3+10e3); // Thevnin equivalent
```

voltage at XX' in volts

- 19 Zth1=10e3\*10e3/(10e3+10e3); // Thevnin equivalent resistance at YY' in ohms
- 20 Vth2=5; // Thevnin equivalent voltage at YY' in volts
- 21 Zth2=5e3; // Thevnin equivalent resistance at YY' in ohms
- 22 // From the figure 2.5(d)
- 23 I=0; // Labelled current in amperes
- 24 Vo=5-7.5; // Labelled voltage in volts
- 25 disp(I,"Labelled current I = ");
- 26 disp(Vo, "Labelled voltage Vo (V) = ");

Scilab code Exa 2.2 Change in diode voltage

```
1 // Example 2.2: Change in diode voltage
2 clc, clear
3 ID1=1; // Let the initial diode current be 1 A
4 ID2=15*ID1; // Final diode current
5 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
6 eta=1; // for Ge
7 deltaVD=eta*VT*log(ID2/ID1); // Change in diode
     voltage in volts
8 deltaVD=deltaVD*1e3; // Change in diode voltage in
      milivolts
9 disp(deltaVD,"Change in diode voltage (for Ge) (mV)
     = "):
10 eta=2; // for Si
11 deltaVD=eta*VT*log(ID2/ID1); // Change in diode
     voltage in volts
12 deltaVD=deltaVD*1e3; // Change in diode voltage in
     milivolts
13 disp(deltaVD," Change in diode voltage (for Si) (mV)
     = ");
```

#### Scilab code Exa 2.3 Germanium diode

```
1 // Example 2.3: (a) Voltage
2 //
                   (b) Ratio of current in forward bias
     to that in reverse bias
                   (c) Forward current
3 //
4 clc, clear
5
6 disp("Part (a)");
7 eta=1; // for Ge
8 T=300; // Room temperature in kelvins
9 VT=T/11600; // Voltage equivalent to temperatue at
     room temperature in volts
10 IS=1; // Let reverse saturation current be 1 A
11 I=-0.9*IS; // Reverse current
12 V=eta*VT*log(1+(I/IS)); // Voltagei in volts
13 V=V*1e3; // Voltage in milivolts
14 disp(V, "Voltage (mV) = ");
15
16 disp("Part (b)");
17 V=0.05; // Voltage in volts
18 If_Ir=(%e^(V/(eta*VT))-1)/(%e^(-V/(eta*VT))-1); //
     Ratio of current in forward bias to that in
     reverse bias
19 disp(If_Ir,"Ratio of current in forward bias to that
      in reverse bias = ");
20
21 disp("Part (c)");
22 IS=10e-6; // Reverse saturation current in amperes
23 V=0.1; // Voltage in volts
24 ID=IS*(%e^(V/(eta*VT))-1); // Forward current for
     0.1 V in amperes
25 ID=ID*1e6; // Forward current for 0.1 V in micro-
     amperes
```

```
26 disp(ID, "Forward current for 0.1 \text{ V} ( A ) = ");
27 V=0.2; // Voltage in volts
```

- 28 ID=IS\*(%e^(V/(eta\*VT))-1); // Forward current for 0.1 V in amperes
- 29 ID=ID\*1e3; // Forward current for 0.1 V in miliamperes
- 30 disp(ID, "Forward current for 0.1 V (mA) = ");
- 31 V=0.3; // Voltage in volts
- 33 disp(ID, "Forward current for 0.1 V(A) = ");

Scilab code Exa 2.4 Diode current

```
1 // Example 2.4 (a) Current
2 //
                  (b) Current
3 //
                  (C) Current
4 clc, clear
5 IS=10e-6; // Reverse saturation current in amperes
6 eta=1; // for Ge
7 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
8
9 disp("Part (a)");
10 VD=-24; // Reverse bias in volts
11 ID=IS*(%e^(VD/(eta*VT))-1); // Current in amperes
12 ID=ID*1e6; // Current in micro-amperes
13 disp(ID, "Current ( A) = ");
14
15 disp("Part (b)");
16 VD=-0.02; // Reverse bias in volts
17 ID=IS*(%e^(VD/(eta*VT))-1); // Current in amperes
18 ID=ID*1e6; // Current in micro-amperes
19 disp(ID, "Current ( A) = ");
20
```

```
21 disp("Part (c)");
22 VD=0.3; // Forward bias in volts
23 ID=IS*(%e^(VD/(eta*VT))-1); // Current in amperes
24 disp(ID,"Current (A) = ");
```

Scilab code Exa 2.5 Change in diode voltage

```
1 // Example 2.2: Change in diode voltage
2 clc, clear
3 T=300; // Operating temperature in kelvins
4 VT=T/11600; // Voltage equivalent to temperatue at
     room temperature in volts
5 ID1=1; // Let the initial diode current be 1 A
6 ID2=10*ID1; // Final diode current
7 eta=1; // for Ge
8 deltaVD=eta*VT*log(ID2/ID1); // Change in diode
     voltage in volts
9 deltaVD=deltaVD*1e3; // Change in diode voltage in
     milivolts
10 disp(deltaVD, "Change in diode voltage (for Ge) (mV)
     = ");
11 eta=2; // for Si
12 deltaVD=eta*VT*log(ID2/ID1); // Change in diode
     voltage in volts
13 deltaVD=deltaVD*1e3; // Change in diode voltage in
     milivolts
14 disp(deltaVD," Change in diode voltage (for Si) (mV)
     = ");
```

Scilab code Exa 2.6 Value of R

```
1 // Example 2.6: R
2 clc, clear
```

- 3 // In the circuit given in Fig. 2.7
- 4 V=50e-3; // Output voltage
- 5 VD1=0.7; // Voltage across diode 1 in volts
- 6 I1=10e-3; // Current through diode 1 at 0.7 V in amperes
- 7 VD2=0.8; // Voltage across diode 2 in volts
- 8 I2=100e-3; // Current through diode 2 at 0.8 V in amperes
- 9 eta\_VT=(VD2-VD1)/log(I2/I1); // Product of and VT

```
11 R=V/I;
```

12 disp(R, "R ( ) = ");

Scilab code Exa 2.7 Solving a circuit with diode

```
1 // Example 2.7: Current, Diode voltage
2 clc, clear
3 VDD=5; // Applied voltage in volts
4 VD=0.7; // Diode voltage in volts
5 I1=1e-3; // Current in amperes at diode voltage =
     0.7 V
6 R=1000; // R in ohms
7 deltaVD=0.1; // Change in diode voltage in volts for
      every decade change in current
8 ratioI=10; // Decade change in current
9 eta_VT=deltaVD/log(ratioI); // Product of
                                                and VT
10 ID=(VDD-VD)/R; // Diode current in amperes
11 VD2=VD+eta_VT*log(ID/I1); // Diode voltage in volts
12 ID=ID*1e3; // Diode current in miliamperes
13 disp(ID, "Diode current (mA) = ");
14 disp(VD2, "Diode voltage (v) = ");
```

Scilab code Exa 2.8 Output voltage

```
1 // Example 2.8: (a) Output voltage
2 //
                   (b) Output voltage
3 //
                   (c) Output voltage
4 clc, clear
5
6 disp("Part (a)");
7 // Since both the diodes are in OFF state
8 Vo=5; // Output voltage in volts
9 disp(Vo, "Output voltage (V) = ");
10
11 disp("Part (b)");
12 //Since diode D1 is in OFF state and diode D2 is in
     ON state
13 // From Fig. 2.16(C)
14 I=(5-0.6)/(4.7e3+300); // Current flowing through
     the diode D2 in amperes
15 Vo=5-I*4.7e3; // Output voltage in volts
16 disp(Vo, "Output voltage (V) = ");
17
18 disp("Part (c)");
19 // Since both diodes are in ON state
20 // Applying KVL in Fig. 2.16(d)
21 I=(5-0.6)/(2*4.7e3+300); // Current flowing through
     diode D1 or diode D2 in amperes
22 Vo=5-2*I*4.7e3; // Output voltage in volts
23 disp(Vo, "Output voltage (V) = ");
```

#### Scilab code Exa 2.9 Circuit parameters

```
1 // Example 2.9 (a) Output voltage, Diode currents
2 // (b) Output voltage, Diode currents
3 clc, clear
4 Vy=0.7; // Cut-in voltage in volts
```

```
5 // In the Fig. 2.17
6 R1=5e3;
7 R2=10e3;
8
9 disp("Part (a)");
10 // Since diode D1 is OFF and diode D2 is ON
11 ID2=(5-Vy-(-5))/(R1+R2); // Current through diode D2
      in amperes
12 Vo=5-ID2*R1; // Output voltage
13 ID2=ID2*1e3; // Current through diode D2 in
      miliamperes
14 disp(Vo,"Output voltage (V) = ");
15 disp(0," Current through diode D1 =");
16 disp(ID2, "Current through diode D2 (mA) =");
17
18 disp("Part (b)");
19 // Since both the diodes are ON
20 VA=4-Vy; // In the fig.
21 Vo=VA+Vy; // Output voltage
22 ID2=(5-Vo)/R1; // Current through diode D2 in
     amperes
23 IR2=(VA-(-5))/R2; // Current through diode R2 in
     amperes
24 ID1=IR2-ID2; // Current through diode D1 in amperes
25 ID1=ID1*1e3; // Current through diode D1 in
     miliamperes
26 ID2=ID2*1e3; // Current through diode D2 in
      miliamperes
27 disp(Vo, "Output voltage (V) =");
28 disp(ID1, "Current through diode D1 (mA) =");
29 disp(ID2, "Current through diode D2 (mA) =");
```

Scilab code Exa 2.11 Solving a circuit with diode

```
1 // Example 2.11 (a) Alternating component of voltage
      acroos load resistance
                   (b) Total voltage across load
2 //
     resistance
3 //
                   (c) Total current
4 clc, clear
5 T=293; // Operating temperature in kelvins
6 VT=T/11600; // Voltage equivalent to temperatue at
     room temperature in volts
7 // In the Fig. 2.21(a)
8 VAA=9; // in volts
9 Vm=0.2; // in volts
10 RL=2e3; // Load resistance in ohms
11 Vy=0.6; // Cut-in voltage in volts
12 Rf=10; // Forward resistance of diode in ohms
13 eta=2;
14
15 disp("Part (a)")
16 // From DC model in Fig. 2.21(b)
17 IDQ=(VAA-Vy)/(RL+Rf); // DC current through diode or
      load resistance in amperes
18 rd=eta*VT/IDQ; // Dynamic resistance in ohms
19 // This dynamic resistance is used in AC model in
     Fig. 2.21(c)
20 Vom=Vm*RL/(RL+rd); // Amplitude of alternating
     component of the voltage across load resistance
     in volts
21 disp(Vom," Amplitude of alternating component of the
     voltage across load resistance (V) = ");
22 disp("Therefore, the alternating component of the
     voltage across load resistance is 0.199 sin t V
     ");
23
24 disp("Part (b)");
25 VDQ=IDQ*RL; // DC component of voltage across load
     resistance in volts
26 disp(VDQ,"DC component of voltage across load
     resistance (V) = ");
```

```
27 disp("Therefore, total voltage across load
      resistance is (8.36 + 0.199 \text{ sin } t) V");
28
29 disp("Part (C)");
30 IDQ=IDQ*1e3; // DC current through load resistance
      in miliamperes
31 idm=Vm/(RL+rd); // Amplitude of alternating
     component of the current across load resistance
     in amperes
32 idm=idm*1e3; // Amplitude of alternating component
     of the current across load resistance in
     miliamperes
33 disp(IDQ,"DC component of current across load
      resistance (mA) = ");
34 disp(idm," Amplitude of alternating component of the
     current across load resistance (mA) = ");
35 disp("Therefore, total current across load
```

resistance is (4.18 + 0.099 sin t) mA";

#### Scilab code Exa 2.12 Diode small signal model

```
1 //Example 2.12: (b) Vo
2 // (c) I
3 clc, clear
4
5 disp("Part (b)");
6 // In the Fig. 2.22 (a)
7 vs=10e-3; // in volts
8 Rs=1e3; // in ohms
9 eta=2;
10 VT=25e-3; // Voltage equivalent to temperatue at
room temperature in volts
11 I=1e-3; // in amperes
12 Vo=vs*eta*VT/(eta*VT+I*Rs); // in volts
13 Vo=Vo*1e3; // in milivolts
```

```
14 disp(Vo, "Vo for I= 1 mA (mV) =");
15 I=0.1e-3; // in amperes
16 Vo=vs*eta*VT/(eta*VT+I*Rs); // in volts
17 Vo=Vo*1e3; // in milivolts
18 disp(Vo, "Vo for I= 0.1 mA (mV) =");
19 I=1e-6; // in amperes
20 Vo=vs*eta*VT/(eta*VT+I*Rs); // in volts
21 Vo=Vo*1e3; // in milivolts
22 disp(Vo, "Vo for I= 1 A (mV) =");
23
24 disp("Part (c)");
25 Vo=vs/2; // in volts
26 I=eta*VT*(vs-Vo)/(Vo*Rs); // in amperes
27 I=I*1e6; // in micro-amperes
28 disp(I,"I ( A ) =");
```

Scilab code Exa 2.13 Barrier capacitance

```
1 // Example 2.13: Barrier capacitance
2 clc, clear
3 A=1e-3*1e-3; // Area of p-n junction in metres
square
4 W=2e-6; // Space charge thickness in metres
5 E=16; // Dielectric constant of Ge
6 Eo=1/(36*%pi*1e9); // Absolute permittivity of air
7 C=E*Eo*A/W; // Barrier capacitance in farads
8 C=C*1e12; // Barrier capacitance in pico-farads
9 disp(C,"Barrier capacitance (pF) =");
```

Scilab code Exa 2.14 Change in capacitance

1 // Example 2.14: (a) Change in capacitance 2 // (b) Change in capacitance

```
3 clc, clear
4 C=4e-12; // Depletion capacitance in farads
5 V=4; // in volts
6 K=C*sqrt(V); // a constant
\overline{7}
8 disp("Part (a)");
9 V=4+0.5; // in volts
10 C_new=K/sqrt(V); // in farads
11 deltaC=C_new-C; // Change in capacitande in farads
12 deltaC=deltaC*1e12; // Change in capacitande in pico
     -farads
13 disp(deltaC, "Change in capacitance (pF) =");
14
15 disp("Part (b)");
16 V=4-0.5; // in volts
17 C_new=K/sqrt(V); // in farads
18 deltaC=C_new-C; // Change in capacitande in farads
19 deltaC=deltaC*1e12; // Change in capacitande in pico
     -farads
20 disp(deltaC, "Change in capacitance (pF) =");
```

Scilab code Exa 2.18 Diffusion length

```
1 // Example 2.18: Diffusion length
2 clc, clear
3 I=1e-3; // Forward bias current in amperes
4 C=1e-6; // Diffusion capacitance in farads
5 Dp=13; // Diffusion constant for Si
6 eta=2; // for Si
7 VT=26e-3; // Voltage equivalent to temperatue at
room temperature in volts
8 Lp=sqrt(C*Dp*eta*VT/I); // Diffusion length in
metres
9 Lp=Lp*1e2; // Diffusion length in centimetres
10 disp(Lp," Diffusion length (cm) =");
```

Scilab code Exa 2.19 Two diodes in series

```
1 // Example 2.19 (a) Vd1 and Vd2
2 //
                   (b) Current in the circuit
3 clc, clear
4 eta_VT=0.026; // Product of
                               and VT
5
6 disp("Part (a)");
7 // From the Fig. 2.19(a)
8 Is=5e-6; // Reverse saturation current through diode
      D2 in amperes
  Id1=Is; // Forward current through diode D1 in
9
     amperes
10 Vd1=eta_VT*log(1+(Id1/Is)); // in volts
11 Vd2=5-Vd1; // in volts
12 disp(Vd1, "Vd1 (V) =");
13 disp(Vd2, "Vd2 (V) =");
14
15 disp("Part (b)");
16 // From the Fig. 2.19(b)
17 Vz=4.9; // Zener voltage in volts
18 Vd1=5-Vz; // in volts
19 I=Is*(%e^(Vd1/eta_VT)-1); // Current in the circuit
     in amperes
20 I=I*1e6; // Current in the circuit in micro-amperes
21 disp(I, "Current in the circuit ( A) =");
```

### Chapter 3

### **Application of Diodes**

Scilab code Exa 3.4 Full wave rectifier

1 // Example 3.4: (a) DC load current 2 // (b) DC power in load 3 // (c) Rectification efficiency 4 // (d) Percentage regulation 5 // (e) PIV of each diode 6 clc, clear 7 Vrms=40; // Input in volts 8 Rf=1; // Forward conduction resistance of diodes in ohms 9 RL=29; // Load resistance in ohms 10 Vmax=Vrms\*sqrt(2); // in volts 11 Imax=Vmax/(Rf+RL); // in amperes 1213 disp("Part (a)"); 14 Idc=2\*Imax/%pi; // DC load current in amperes 15 disp(Idc, "DC load current (A) ="); 1617 disp("Part (b)"); 18 Pdc=Idc^2\*RL; // DC power in load in watts 19 disp(Pdc,"DC power in load (W) ="); 20

```
21 disp("Part (c)");
22 Pac=Vrms^2/(Rf+RL); // AC power in load
23 eta=Pdc/Pac; // Rectification efficiency
24 disp(eta,"Rectification efficiency =");
25
26 disp("Part (d)");
27 reg=Rf*100/RL; // Percentage regulation
28 disp(reg,"Percentage regulation (%) =");
29
30 disp("Part (e)");
31 PIV=2*Vmax; // in volts
32 disp(PIV,"PIV for each diode (V) =");
```

Scilab code Exa 3.5 Full wave bridge rectifier

```
1 // Example 3.5: (a) DC voltage at load
2 //
                   (b) PIV rating of each diode
                   (c) Maximum current through each
3 //
     diode
4 //
                   (d) Required power rating
5 clc, clear
6 Vrms=120; // Input voltage in volts
7 RL=1e3; // Load resistance in ohms
8 Vy=0.7; // Cut-in voltage in volts
9
10 disp("Part (a)");
11 Vmax=Vrms*sqrt(2); // in volts
12 Imax=(Vmax-2*Vy)/RL; // in amperes
13 Idc=2*Imax/%pi; // in amperes
14 Vdc=Idc*RL; // in volts
15 disp(Vdc, "DC voltage at load (V) =");
16
17 disp("Part (b)");
18 disp(Vmax,"PIV rating of each diode (V) =");
19
```

```
20 disp("Part (c)");
21 Imax=Imax*1e3; // in miliamperes
22 disp(Imax,"Maximum current through each diode (mA) =
        ");
23
24 disp("Part (d)");
25 Pmax=Vy*Imax; // Required power rating in mili-watts
26 disp(Pmax,"Required power rating (mW) =");
```

Scilab code Exa 3.6 Centre tapped full wave rectifier

```
1 // Example 3.6: (a) Peak value of current
2 //
                   (b) DC value of current
3 //
                   (c) Ripple factor
                   (d) Rectification efficiency
4 //
5 clc, clear
6 // From the Fig. 2.16
7 RL=1e3; // Load resistance in ohms
8 rd=10; // Forward bias dynamic resistance of diodes
     in ohms
9 Vmax=220; // Amplitude of input voltage in volts
10
11 disp("Part (a)");
12 Imax=Vmax/(rd+RL); // Peak value of current in
     amperes
13 disp(Imax, "Peak value of current (A) =");
14
15 disp("Part (b)");
16 Idc=2*Imax/%pi; // DC value of current in amperes
17 disp(Idc, "DC value of current (A) =");
18
19 disp("Part (C)");
20 ripl=sqrt((Imax/(Idc*sqrt(2)))^2-1);
21 disp(ripl," Ripple factor =");
22
```

```
23 disp("Part (d)");
24 eta=8/(%pi^2*(1+(rd/RL))); // Rectification
efficiency
25 disp(eta," Rectification efficiency =");
```

Scilab code Exa 3.7 Full scale reading

```
1 // Example 3.7: Full scale reading
2 clc, clear
3 Idc=1e-3; // in amperes
4 Rf=10; // in ohms
5 RL=5e3; // in ohms
6 Vrms=Idc*(RL+Rf)*%pi/(2*sqrt(2)); // Full-scale
        deflection in volts
7 disp(Vrms, "Full-scale deflection (V) =");
```

Scilab code Exa 3.8 Full scale reading

```
1 // Example 3.8: Full-scale reading
2 clc, clear
3 Idc=5e-3; // in amperes
4 Rf=40; // in ohms
5 RL=20e3; // in ohms
6 Vrms=Idc*(RL+Rf)*%pi/(2*sqrt(2)); // Full-scale
        deflection in volts
7 disp(Vrms, "Full-scale deflection (V) =");
```

Scilab code Exa 3.10 Minimum and maximum value of zener diode current

```
1 // Example 3.10: Minimum and maximum value of zener
     diode current
2 clc, clear
3 // From the Fig. 3.33
4 Vsmin=120; // in volts
5 Vsmax=170; // in volts
6 Vz=50; // in volts
7 Rs=5e3; // in ohms
8 RLmin=5e3; // in ohms
9 RLmax=10e3; // in ohms
10 ILmin=Vz/RLmax; // in amperes
11 ILmax=Vz/RLmin; // in amperes
12 Izmin=((Vsmin-Vz)/Rs)-ILmax; // Minimum value of
     zener diode current in amperes
13 Izmin=Izmin*1e3; // Minimum value of zener diode
     current in miliamperes
14 Izmax=((Vsmax-Vz)/Rs)-ILmin; // Maximum value of
     zener diode current in amperes
15 Izmax=Izmax*1e3; // Maximum value of zener diode
     current in miliamperes
16 disp(Izmin," Minimum value of zener diode current (mA
     ) =");
17 disp(Izmax," Maximum value of zener diode current (mA
     ) =");
```

#### Scilab code Exa 3.11 Safe voltage range

```
1 // Example 3.11: (a) V
2 // (b) Voltage range of V
3 clc, clear
4 Vz=50; // Zener voltage in volts
5 Izmin=1e-3; // in amperes
6 Izmax=5e-3; // in amperes
7
8 disp("Part (a)");
```

```
9 ILmin=0;
10 Rs=5e3; // in ohms
11 V=Vz+Rs*(Izmax+ILmin); // in volts
12 disp(V,"V (V) =");
13
14 disp("Part (b)");
15 IL=(50/15)*1e-3; // in amperes
16 Vmin=Vz+Rs*(Izmin+IL); // in volts
17 Vmax=Vz+Rs*(Izmax+IL); // in volts
18 disp(Vmin,"Vmin (V) =");
19 disp(Vmax,"Vmax (V) =");
```

Scilab code Exa 3.12 Voltage regulator

```
1 // Example 3.12: Zener diode current, Power
      dissipation in zener diode and resistor
2 clc, clear
3 // In the Fig. 3.35
4 Vz=6.8; // in volts
5 R=100; // in ohms
6
7 disp("Normal situation");
8 Vs=9; // in volts
9 I = (Vs - Vz)/R; // in amperes
10 Pzener=I*Vz; // in watts
11 Presistor=I^2*R; // in watts
12 I=I*1e3; // in miliamperes
13 Pzener=Pzener*1e3; // in miliwatts
14 Presistor=Presistor*1e3; // in miliwatts
15 disp(I,"Zener diode current (mA) =");
16 disp(Pzener,"Power dissipation in zener diode (mW) =
     "):
17 disp(Presistor," Power dissipation in resistor (mW) =
     ");
18
```

```
19 disp("Aberrant situation");
20 Vs=15; // in volts
21 I=(Vs-Vz)/R; // in amperes
22 Pzener=I*Vz; // in watts
23 Presistor=I^2*R; // in watts
24 I=I*1e3; // in miliamperes
25 Pzener=Pzener*1e3; // in miliwatts
26 Presistor=Presistor*1e3; // in miliwatts
27 disp(I,"Zener diode current (mA) =");
28 disp(Pzener,"Power dissipation in zener diode (mW) =
        ");
29 disp(Presistor,"Power dissipation in resistor (mW) =
        ");
```

Scilab code Exa 3.13 Range of load current

```
1 // Example 3.13: Range of load current
2 clc, clear
3 Vz=5; // in volts
4 Izmin=50e-3; // in amperes
5 Izmax=1; // in amperes
6 Vmin=7.5; // in volts
7 Vmax=10; // in volts
8 Rs=4.75; // in ohms
9 ILmin=((Vmax-Vz)/Rs)-Izmax; // in amperes
10 ILmin=ILmin*1e3; // in miliamperes
11 ILmax=((Vmin-Vz)/Rs)-Izmin; // in amperes
12 ILmax=ILmax*1e3; // in miliamperes
13 disp(ILmin,"ILmin (mA) =");
14 disp(ILmax,"ILmax (mA) =");
```

Scilab code Exa 3.14 Zener diode

```
1 // Exmaple 3.14: Load-current range, Series
     resistance in redesigned circuit
2 clc, clear
3 // In Fig. 3.37
4 Vz=6.8; // in volts
5 Izk=0.1e-3; // in amperes
6 Vs=10; // in volts
7 Rs=1e3; // in ohms
8 ILmax=((Vs-Vz)/Rs)-Izk; // in amperes
9 ILmax=ILmax*1e3; // in miliamperes
10 disp(0,"ILmin =");
11 disp(ILmax, "ILmax (mA) =");
12
13 disp("Redesigned Part")
14 RL=1e3; // in ohms
15 Izk=Izk*10; // in amperes
16 I=Izk+(Vz/RL); // in amperes
17 R=(Vs-Vz)/I; // in ohms
18 disp(R, "Series resistance () =");
```

#### Scilab code Exa 3.15 Zener diode regulator

```
1 // Example 3.15: (a) Series resistance
2 // (b) Power dissipation rating of
zener diode
3 clc, clear
4 // In Fig. 3.38
5 Vz=6; // in volts
6 ILmin=0;
7 ILmax=0.5; // in amperes
8 Vmin=8; // in volts
9 Vmax=10; // in volts
10 Izmin=0;
11
12 disp("Part (a)");
```
```
13 Rs=(Vmin-Vz)/(ILmax+Izmin); // Series resistance in
ohms
14 disp(Rs, "Series resistance ( ) =");
15
16 disp("Part (b)");
17 Izmax=((Vmax-Vz)/Rs)-ILmin; // in amperes
18 Pzmax=Vz*Izmax; // in watts
19 disp(Pzmax, "Power dissipation rating of zener diode
(W) =");
```

### Scilab code Exa 3.16 Zener diode

```
1 // Example 3.16: Series resistance R, Maximum zener
     current
2 clc, clear
3 // In Fig. 3.39
4 Vz=7.2; // in volts
5 ILmin=12e-3; // in amperes
6 ILmax=100e-3; // in amperes
7 Vs=20; // in volts
8 Izmin=10e-3; // in amperes
9 Rs=(Vs-Vz)/(ILmax+Izmin); // Series resistance in
     ohms
10 disp(Rs, "Series resistance () =");
11 // For ILmin=0
12 Izmax=((Vs-Vz)/Rs); // in amperes
13 Izmax=Izmax*1e3; // in miliamperes
14 disp(Izmax, "Maximum zener current (mA) =");
```

## Scilab code Exa 3.17 Avalanche diode

1 // Example 3.17: (a) R, maximum possible value of load current

```
(b) Range of V
2 //
3 clc, clear
4 Vz=50; // Diode voltage in volts
5 Izmin=5e-3; // in amperes
6 Izmax=40e-3; // in amperes
7
8 disp("Part (a)");
9 ILmin=0;
10 V=200; // Input voltage in volts
11 R=(V-Vz)/(Izmax-ILmin); // in ohms
12 ILmax=((V-Vz)/R)-Izmin; // in amperes
13 Rk=R*1e-3; // in kilo-ohms
14 ILmax=ILmax*1e3; // in miliamperes
15 disp(Rk, "R(k) =");
16 disp(ILmax," Maximum possible value of load current (
     mA) = ");
17
18 disp("Part (b)");
19 IL=25e-3;
20 Vmin=Vz+R*(Izmin+IL); // in volts
21 Vmax=Vz+R*(Izmax+IL); // in volts
22 disp(Vmin, "Minimum value of V (V) =");
23 disp(Vmax, "Maximum value of V (V) =");
```

### Scilab code Exa 3.18 Zener diode

```
1 // Example 3.18: R, ILmax, Power rating of zener
diode
2 clc, clear
3 // In Fig. 3.41
4 Vz=6; // in volts
5 V=22; // in volts
6 Izmin=10e-3; // in amperes
7 Izmax=40e-3; // in amperes
8 ILmin=0;
```

```
9 R=(V-Vz)/(Izmax-ILmin); // in ohms
10 ILmax=((V-Vz)/R)-Izmin; // in amperes
11 P=Izmax*Vz; // Power rating of zener diode in watts
12 ILmax=ILmax*1e3; // in miliamperes
13 P=P*1e3; // Power rating of zener diode in mili-
watts
14 disp(R,"R( ) =");
15 disp(ILmax,"ILmax (mA) =");
16 disp(P,"Power rating of zener diode (mW) =");
```

Scilab code Exa 3.19 Zener diode

```
1 // Example 3.19: (a) VL, IL, Iz, IR
2 //
                    (b) RL for maximum power
      dissipation for zener diode
3 //
                   (c) Maximum value of RL for zener
     diode to remain ON
4 clc, clear
5 // From Fig. 3.42
6 Vs=25; // in volts
7 Rs=220; // in ohms
8 Vz=10; // in volts
9 Pzmax=400; // in mili-watts
10 Izmax=Pzmax/Vz; // in miliamperes
11 Izmin=Izmax*10/100; // in miliamperes
12
13 disp("Part (a)");
14 RL=180; // in ohms
15 VL=Vz; // in volts
16 IL=Vz/RL; // in amperes
17 IL=IL*1e3; // in miliamperes
18 IR=(Vs-Vz)/Rs; // in amperes
19 IR=IR*1e3; // in miliamperes
20 Iz=IR-IL; // in miliamperes
21 disp(VL, "VL (V) =");
```

```
22 disp(IL,"IL (mA) =");
23 disp(Iz, "Iz (mA) =");
24 disp(IR, "IR (mA) =");
25
26 disp("Part (b)");
27 RL=Vz*1e3/(IR-Izmax); // in ohms
28 disp(RL,"RL for maximum power dissipation for zener
      diode ( ) =");
29
30 disp("Part (c)");
31 RL=Vz*1e3/(IR-Izmin); // in ohms
32 disp(RL," Maximum value of RL for zener diode to
     remain ON () = ");
33 disp("If Izmin=0");
34 RL=Vz*1e3/IR; // in ohms
35 disp(RL," Maximum value of RL for zener diode to
     remain ON () = ");
```

Scilab code Exa 3.20 Regulation range of zener diode

```
1 // Example 3.20: Range and average watage of Rs
2 clc, clear
3 // From Fig. 3.43
4 Vsmin=20; // in volts
5 Vsmax=30; // in volts
6 RLmin=1; // in ohms
7 RLmax=10; // in ohms
8 Izmin=10e-3; // in amperes
9 Pzmax=50; // in watts
10 Vz=10; // in volts
11 ILmin=Vz/RLmax; // in amperes
12 ILmax=Vz/RLmin; // in amperes
13 Izmax=Pzmax/Vz; // in amperes
14 Rs1=(Vsmin-Vz)/(ILmax+Izmin); // in ohms
15 Rs2=(Vsmax-Vz)/(ILmin+Izmax); // in ohms
```

```
16 disp(Rs1, "Rs <= ");
17 disp(Rs2, "Rs >= ");
18 disp("To meet the load current variation from 1 A to
      10 A a zener of specification Izmin = 0.01 A to
     Izmax = 5 A cannot meet the requirement for any
     value of Rs")
19 // Let
20 RLmin=1e3; // in ohms
21 RLmax=10e3; // in ohms
22 ILmin=Vz/RLmax; // in amperes
23 ILmax=Vz/RLmin; // in amperes
24 Rsmin=(Vsmax-Vz)/(ILmin+Izmax); // in ohms
25 Rsmax=(Vsmin-Vz)/(ILmax+Izmin); // in ohms
26 disp(Rsmin,"Minimum value of Rs (
                                       ) = ");
27 disp(Rsmax, "Maximum value of Rs ( ) =");
28 Rs=4; // in ohms
29 W=Rs*(ILmax+Izmax)^2; // in watts
30 disp(W,"Average wattage of Rs (W) =");
```

Scilab code Exa 3.21.a Clipping circuits

```
1 // Example 3.21: (a) Transfer characteristics and
output
2 // (b) Transfer characteristics and
output
3 clc, clear
4 Vy=0.6; // in volts
5 Rf=100; // in ohms
6 t=[-40:0.001:40];
7 vin=40*sin(2*%pi*t/80); // Input voltage in volts
8
```



Figure 3.1: Clipping circuits



Figure 3.2: Clipping circuits

```
9 // Part (a)
10 // From Fig. 3.49(a)
11 // Sketching of transfer characteristics
12 for i=1:length(vin)
13
      if vin(i) < 5.6 then
14
           vo(i)=vin(i); // in volts
15
      else
           ID=(vin(i)-5.6)/(4.9e3+Rf); // in amperes
16
           vo(i)=vin(i)-ID*4.9e3; // in volts
17
18
       end
19 end
20 plot(vin,vo);
21 xtitle("Part (a) - Transfer characteristics", "vin","
      vo");
22 // Sketching of output
23 scf(1);
24 plot(t,vin,"---");
25 plot(t,vo);
26 xtitle("Part (a) - Output voltage and input voltage"
     ," t ","vo,vin");
27 legend("vin","vo");
28
29 // Part (b)
30 // From Fig. 3.49(b)
31 // Sketching of transfer characteristics
32 for i=1:length(vin)
33
       if vin(i)>-0.6 then
           vo(i)=vin(i); // in volts
34
35
       else
           ID = (vin(i) + 0.6) / (9.9e3 + Rf); // in amperes
36
           vo(i)=vin(i)-ID*9.9e3; // in volts
37
38
       end
39 end
40 scf(2);
41 plot(vin,vo);
42 xtitle("Part (b) - Transfer characteristics", "vin","
      vo");
43 // Sketching of output
```



Figure 3.3: Range of load current

```
44 scf(3);
45 plot(t,vin,"---");
46 plot(t,vo);
47 xtitle("Part (b) - Output voltage and input voltage"
        ," t","vo,vin");
48 legend("vin","vo");
```

## Scilab code Exa 3.21.b Range of load current

```
1 // Example 3.21: (a) Transfer characteristics and
output
2 // (b) Transfer characteristics and
output
```



Figure 3.4: Range of load current

```
3 clc, clear
4 Vy=0.6; // in volts
5 Rf=100; // in ohms
6 t = [-40:0.001:40];
7 vin=40*sin(2*%pi*t/80); // Input voltage in volts
8
9 // Part (a)
10 // From Fig. 3.49(a)
11 // Sketching of transfer characteristics
12 for i=1:length(vin)
13
       if vin(i) < 5.6 then
           vo(i)=vin(i); // in volts
14
15
       else
           ID=(vin(i)-5.6)/(4.9e3+Rf); // in amperes
16
           vo(i)=vin(i)-ID*4.9e3; // in volts
17
18
       end
19 end
20 plot(vin,vo);
21 xtitle("Part (a) - Transfer characteristics", "vin","
```

```
vo");
22 // Sketching of output
23 scf(1);
24 plot(t,vin,"---");
25 plot(t,vo);
26 xtitle("Part (a) - Output voltage and input voltage"
     ," t ","vo,vin");
27 legend("vin","vo");
28
29 // Part (b)
30 // From Fig. 3.49(b)
31 // Sketching of transfer characteristics
32 for i=1:length(vin)
       if vin(i)>-0.6 then
33
           vo(i)=vin(i); // in volts
34
35
       else
           ID = (vin(i) + 0.6) / (9.9e3 + Rf); // in amperes
36
37
           vo(i)=vin(i)-ID*9.9e3; // in volts
38
       end
39 end
40 scf(2);
41 plot(vin,vo);
42 xtitle("Part (b) - Transfer characteristics", "vin","
      vo");
43 // Sketching of output
44 scf(3);
45 plot(t,vin,"---");
46 plot(t,vo);
47 xtitle("Part (b) - Output voltage and input voltage"
     ," t ","vo,vin");
48 legend("vin","vo");
```



Figure 3.5: Transfer characteristics



Figure 3.6: Transfer characteristics

Scilab code Exa 3.22 Transfer characteristics

```
1 // Example 3.22: (a) Transfer characteristics
2 //
                     (b) Transfer characteristics
3 clc, clear
4 t=[0:0.1:20]; // in mili-seconds
5 vin=30*t/10; // Input voltage in volts
6 // From Fig. 3.52(b)
7
8 // Part {a}
9 // Sketching of transfer characteristics
10 for i=1:length(vin)
11
       if vin(i)>25 then
           vo(i)=5; // in volts
12
13
      else
           IL=vin(i)/(200+50); // in amperes
14
           vo(i)=IL*50; // in volts
15
16
       end
17 end
18 plot2d(vin,vo,rect=[0,0,60,6]);
19 xtitle("Part (a) - Transfer characteristics", "vin","
     vo");
20
21 // Part (b)
22 // Sketching of transfer characteristics
23 Vy=0.5; // in volts
24 Rf=40; // in ohms
25 VA=5+0.5; // in volts
26 for i=1:length(vin)
27
       if vin(i) <27.5 then
           IL=vin(i)/(200+50); // in amperes
28
29
           vo(i)=IL*50; // in volts
30
       else
31
           IL=(vin(i)+27.5)/500; // in amperes
           vo(i)=IL*50; // in volts
32
33
       end
34 end
35 scf(1);
```



Figure 3.7: Clipping circuit

# Scilab code Exa 3.23 Clipping circuit

```
1 // Example 3.23: Output voltage and transfer
characteristic curve
2 clc, clear
3 t=[-6:0.001:6];
4 vin=6*sin(2*%pi*t/12); // Input voltage in volts
5 // Sketching of output voltage
6 for i=1:length(vin)
```



Figure 3.8: Clipping circuit

```
if vin(i)>=2 then
7
           // From Fig. 3.54(b), D1 ON and D2 OFF
8
           I1=(vin(i)-2)/(10e3+10e3); // in amperes
9
           vo(i)=vin(i)-I1*10e3; // in volts
10
       elseif vin(i)>=-4 then
11
12
           // both D1 and D2 OFF
13
           vo(i)=vin(i);
14
       else
           // From Fig. 3.54(c), D1 OFF and D2 ON
15
           vo(i) = -4; // in volts
16
17
       end
18 end
19 plot(t,vin,"---");
20 plot(t,vo);
21 xtitle("Output voltage and input voltage"," t","vo,
      vin");
22 legend("vin","vo");
23 // Sketching of transfer characteristic curve
24 scf(1);
```



Figure 3.9: Transfer characteristics

```
25 plot2d(vin,vo,rect=[-6,-6,6,6]);
26 xtitle("Transfer characteristic curve","vin","vo");
```

Scilab code Exa 3.24 Transfer characteristics

```
1 // Example 3.24: Voltage transfer characteristics
2 clc, clear
3 vin=[-2.5:2.5]; // Input voltage in volts
4 // Obtaining thevnin's equivalent circuit on LHS of
XX'
5 V_th=vin*7.5e3/(7.5e3+15e3); // in volts
6 R_th=15e3*7.5e3/(15e3+7.5e3); // in ohms
7 // Sketching of voltage transfer characteristics
8 // From thevnin's equivalent circuit in Fig. 3.55(b)
9 for i=1:length(vin)
```



Figure 3.10: Clipping circuit

```
if vin(i)>1.8 then
10
            I1=(V_th(i)-0.6)/(5e3+R_th); // in amperes
11
            vo(i)=I1*5e3; // in volts
12
       elseif vin(i)>-1.8 then
13
14
            vo(i)=0;
15
       else
16
            I2=(V_th(i)+0.6)/(4e3+R_th); // in amperes
            vo(i)=I2*5e3; // in volts
17
18
       end
19 \quad \texttt{end}
20 plot(vin,vo);
21 xtitle("Voltage transfer characteristics", "vin", "vo"
      );
```



Figure 3.11: Clipping circuit

## Scilab code Exa 3.25 Clipping circuit

```
1 // Example 3.25: (a) Output voltage waveform
2 //
                     (b) Transfer curve
3 clc, clear
4 t = [0:0.001:12];
5 vin=15*sin(2*%pi*t/12); // Input voltage in volts
6 // From Fig. 3.56(a)
  // Sketching of output voltage waveform
7
8
  for i=1:length(vin)
       if vin(i) <16/3 then
9
           // D1 OFF and D2 ON
10
           I2=(10-3)/(20e3+10e3); // in amperes
11
12
           vo(i)=10-I2*20e3; // in volts
13
       elseif vin(i) <=10 then</pre>
           // both D1 and D2 ON
14
```



Figure 3.12: Range of load current

```
vo(i)=vin(i);
15
16
       else
           // D1 ON and D2 OFF
17
           vo(i)=10; // in volts
18
19
       end
20 \text{ end}
21 plot(t,vin,"---");
22 plot(t,vo);
23 xtitle("Output voltage and input voltage"," t","vo,
      vin");
24 legend("vin","vo");
25 // Sketching of transfer curve
26 scf(1);
27 plot2d(vin,vo,rect=[0,0,15,12]);
28 xtitle("Transfer characteristic curve", "vin", "vo");
```



Figure 3.13: Range of load current

#### Scilab code Exa 3.26 Range of load current

```
1 // Example 3.26: Transfer characteristics and output
      and input voltage
2 clc, clear
3 T=60; // Let T = 60 seconds
4 t = [0:T];
5 vin=120*t/T; // Input voltage in volts
6 // From Fig. 3.57(a)
7
  // Sketching of transfer characteristics
8 for i=1:length(vin)
       if vin(i) <=15 then</pre>
9
           // Both D1 and D2 OFF
10
           vo(i)=15; // in volts
11
```

```
12
       elseif vin(i) <=105 then</pre>
13
           // D1 OFF and D2 ON
           I2=(vin(i)-15)/(100e3+200e3); // in amperes
14
           vo(i)=vin(i)-I2*100e3; // in volts
15
16
       else
17
           // Both D1 and D2 ON
           vo(i)=75; // in volts
18
19
       end
20 end
21 plot(vin,vo);
22 xtitle("Transfer characteristics","vin","vo");
23 // Sketching of output
24 scf(1);
25 plot(t,vin,"---");
26 plot(t,vo);
27 xtitle("Output voltage and input voltage"," t","vo,
      vin");
28 legend("vin", "vo");
```

Scilab code Exa 3.27 Range of load current

```
1 // Example 3.27: vo vs vin
2 clc, clear
3 vin=[0:50]; // Input voltage in volts
4 // Sketching of vo vs vin
5 for i=1:length(vin)
6
       if vin(i)<3 then</pre>
           // From Fig. 3.58(b), D1 ON, D2 and D3 OFF
7
           I1=6/(5e3+5e3); // in amperes
8
           vo(i)=I1*5e3; // in volts
9
       elseif vin(i)<9 then</pre>
10
           // From Fig. 3.58(c), D1 and D3 ON, D2 OFF
11
           // Applying Kirchoff's laws
12
```



Figure 3.14: Range of load current

```
vo(i)=0.5*vin(i)+1.5; // in volts
13
       elseif vin(i)<30 then</pre>
14
           // From Fig. 3.58(d), D3 ON, D1 and D2 OFF
15
16
           I3=vin(i)/(2.5e3+5e3); // in amperes
           vo(i)=I3*5e3; // in volts
17
18
       else
           // From Fig. 3.58(e), D2 and D3 ON, D1 OFF
19
           // Applying Kirchoff's laws
20
21
           vo(i)=4*vin(i)/7+20/7; // in volts
22
       end
23 end
24 plot(vin,vo);
25 xtitle("Voltage transfer characteristics", "vin", "vo"
      );
```



Figure 3.15: Transfer characteristics

Scilab code Exa 3.28 Transfer characteristics

```
1 // Example 3.28: Output voltage
2 clc, clear
3 t=[0:5]; // in seconds
4 vs=10*t/5; // Input voltage in volts
  // Output voltage
5
  for i=1:length(vs)
6
7
       if vs(i) <6 then
           // Diode is OFF
8
           vo(i)=6; // in volts
9
10
       else
11
           // From Fig. 3.65(c), Diode is ON
           I=(vs(i)-6)/(200+200); // in amperes
12
           vo(i)=6+I*200; // in volts
13
14
       end
15 \text{ end}
16 plot2d(t,vo,rect=[0,0,5,8]);
17 xtitle("Output voltage","t,ms","vo(t)");
```



Figure 3.16: Output voltage

# Scilab code Exa 3.29 Output voltage

```
1 // Example 3.29: Output voltage
2 clc, clear
3 Vy=0.5; // in volts
4 Rf=50; // in ohms
5 t=[0:5]; // in seconds
6 vs=10*t/5; // Input voltage in volts
  // Output voltage
7
8
  for i=1:length(vs)
9
       if vs(i)<6.5 then
            // Diode is OFF
10
            vo(i)=6; // in volts
11
12
       else
```



Figure 3.17: EX30

## Scilab code Exa 3.30 EX30

```
1 // Example 3.30: (a) Output waveform
2 // (b) Output waveform
3 clc, clear
```



Figure 3.18: EX30

```
4 t=[0:0.001:12];
5 vin=15*sin(2*%pi*t/12); // Input voltage in volts
6
7 // Part (a), From Fig. 3.67(a)
8 vo=vin-15; // in volts
9 plot(t,vo);
10 xtitle("Part (a) - Output voltage","t","vo");
11
12 // Part(b), From Fig. 3.67(b)
13 vo=vin-10; // in volts
14 scf(1);
15 plot(t,vo);
16 xtitle("Part (b) - Output voltage","t","vo");
```

Scilab code Exa 3.31 Output waveform



Figure 3.19: Output waveform

```
1 // Example 3.31: Output voltage
2 clc, clear
3 t=[0:0.1:9*%pi];
4 vin=15*squarewave(t)-5; // Input wave in volts
5 vo=vin+25; // in volts
6 plot2d(t,vo,rect=[0,0,9*%pi,40]);
7 xtitle("Output voltage","t","vo");
```

# Scilab code Exa 3.32 Clamping circuit

```
1 // Example 3.32: Output voltage
2 clc, clear
3 t1=[0:20];
4 vin1=t1;
5 t2=[20:60];
```



Figure 3.20: Clamping circuit

```
6 vin2=40-t2;
7 t3=[60:80];
8 vin3=-80+t3;
9 t=[t1 t2 t3];
10 vin=[vin1 vin2 vin3]; // Input wave in volts
11 vo=vin+25; // in volts
12 plot(t,vo);
13 xtitle("Output voltage","t","vo");
```

### Scilab code Exa 3.33 Clamping circuit

```
1 // Example 3.33: vo
2 clc, clear
3 t=[0:0.001:12];
4 vin=10*sin(2*%pi*t/4); // Input voltage in volts
```



Figure 3.21: Clamping circuit

```
5 // From Fig. 3.73
6 vint=vin+5;
7 for i=1:length(vint)
       if vint(i)>0 then
8
            // Diode is OFF
9
            vo(i)=vint(i); // in volts
10
11
       else
12
            break;
13
       end
14
  end
15 for i=i:length(vint)
       if vint(i)==-5 then
16
17
            break;
18
       else
            // Diode is ON
19
            vo(i)=0;
20
21
       end
22 \text{ end}
23 for i=i:length(vint)
```

# Chapter 4

# **Bipolar Junction Transistors**

Scilab code Exa 4.1 Value of Collector Current

```
1 // Example 4.1: New value of Ic

2 clc, clear

3 VA=100; // Early voltage in volts

4 VCE_old=1; // in volts

5 Ic_old=1e-3; // in amperes

6 VCE_new=11; // in volts

7 ro=VA/Ic_old; // Output resistance in ohms

8 Ic_new=(VCE_new-VCE_old+Ic_old*ro)/ro; // in amperes

9 Ic_new=Ic_new*1e3; // in miliamperes

10 disp(Ic_new,"New value of Ic (mA) =");
```

Scilab code Exa 4.2 CE transistor

```
1 // Example 4.2: Region of operation, All the node
      voltages and currents
2 clc, clear
3 betaf=100; // Current gain
4 disp("Let us assume that the transistor is in active
      region.");
```

```
5 VBE_active=0.7; // in volts
6 // From the equivalent circuit in Fig. 4.18(b)
7 VCC=10; // in volts
8 VBB=4; // in volts
9 RE=3.3e3; // in ohms
10 RC=5e3; // in ohms
11 VE=VBB-VBE_active; // in volts
12 // Writing KVL for base emitter loop and putting Ic =
        F * Ib
13 IB=VE/((1+betaf)*RE); // in amperes
14 IB=IB*1e3; // in miliamperes
15 IC=betaf*IB; // in miliamperes
16 IE=IB+IC; // in miliamperes
17 VC=VCC-IC*RC*1e-3; // in volts
18 disp(VC, "VC (V) =");
19 disp(VE, "VE (V) =");
20 disp(VBB, "VB (V) =");
21 disp(IC,"IC (mA) =");
22 disp(IE, "IE (mA) =");
23 disp(IB, "IB (mA) =");
24 disp("Since the base is at 4 V and the collector is
     at 5.05 V, so the collector junction is reverse
     biased by 1.05 V. The transistor is indeed in
     forward active region as assumed.")
```

# Scilab code Exa 4.3 CE transistor

```
1 // Example 4.3: Region of operation, Node currents
and voltages
2 clc, clear
3 betaf=100; // Current gain
4 disp("Let us assume that the transistor is in active
region.");
5 VBE_active=0.7; // in volts
6 // From Fig. 4.19
```

```
7 VCC=10; // in volts
8 VBB=5; // in volts
9 RB=100e3; // in ohms
10 RE=2e3; // in ohms
11 RC=2e3; // in ohms
12 // Writing KVL to the base circuit and putting Ic =
       F *Ib
13 IB=(VBB-VBE_active)/(RB+(1+betaf)*RE); // in amperes
14 IB=IB*1e3; // in miliamperes
15 IC=betaf*IB; // in miliamperes
16 IE=IB+IC; // in miliamperes
17 VB=VBB-IB*RB*1e-3; // in volts
18 VE=IE*RE*1e-3; // in volts
19 VC=VCC-IC*RC*1e-3; // in volts
20 disp(VC, "VC (V) =");
21 disp(VE, "VE (V) =");
22 disp(VB, "VB (V) =");
23 disp(IC,"IC (mA) =");
24 disp(IE, "IE (mA) =");
25 disp(IB, "IB (mA) =");
26 disp("Since base voltage VB is 3.6 V and collector
     is at 7.2 V, so collector-base junction is
     reverse biased by 3.6 V. Thus our assumption that
      the transistor is in active region is valid.")
```

Scilab code Exa 4.4 Region of Operation

```
1 // Example 4.4: Region of operation
2 clc, clear
3 betaf=100; // Current gain
4 disp("Let us assume that the transistor is in
saturation region.");
5 VBE_sat=0.8; // in volts
6 VCE_sat=0.2; // in volts
7 // From Fig. 4.21
```

```
8 VCC=10; // in volts
9 VBB=5; // in volts
10 RB=50e3; // in ohms
11 RC=2e3; // in ohms
12 // From the base loop
13 IB=(VBB-VBE_sat)/RB; // in amperes
14 IB=IB*1e3; // in miliamperes
15 IC_sat=(VCC-VCE_sat)/RC; // in amperes
16 IC_sat=IC_sat*1e3; // in miliamperes
17 IB_min=IC_sat/betaf; // in miliamperes
18 disp(IB_min," Minimum IB required to saturate the
      transistor (mA) = ");
19 disp(IB,"IB in the circuit (mA) =");
20 disp("Since IB in the circuit is calculated as 0.084
      mA, so it is greater than IB, min. Thus the
      transistor is indeed in saturation mode.")
```

### Scilab code Exa 4.5 Saturation region

```
1 // Example 4.5: Value of RB so as to drive the
     transistor into saturation
2 clc, clear
3 bta=50; // Current gain
4 VBE_sat=0.8; // in volts
5 VCE_sat=0.2; // in volts
6 // From Fig. 4.22
7 VCC=10; // in volts
8 VBB=5; // in volts
9 RC=1e3; // in ohms
10 IC_sat=(VCC-VCE_sat)/RC; // in amperes
11 IB_min=IC_sat/bta; // Minimum base current in
     amperes to saturate the transistor
12 // Then base current can be taken as
13 IB=10*IB_min; // in amperes
14 RB=(VBB-VBE_sat)/IB; // in ohms
```

```
15 RB=RB*1e-3; // in kilo-ohms
16 disp(RB, "Value of RB so as to drive the transistor
            into saturation ( k ) =");
```

Scilab code Exa 4.6 Output voltages

```
1 // Example 4.6: Vo1, Vo2
2 clc, clear
3 betaf=100; // Current gain
4 disp("Let us assume that the transistor is in active
      region.");
5 VBE_active=-0.7; // in volts
6 // From Fig. 4.23
7 VCC=-10; // in volts
8 VEE=10; // in volts
9 VBB=2.5; // in volts
10 RE=6.8e3; // in ohms
11 RB=100e3; // in ohms
12 RC=10e3; // in ohms
13 // Writing KVL for base-emitter circuit and putting
     Ic = F * Ib
14 IB=(VEE-VBB+VBE_active)/(RB+(1+betaf)*RE); // in
     amperes
15
16 IC=betaf*IB; // in amperes
17 IE=IB+IC; // in amperes
18 Vo1=VCC+IC*RC; // in volts
19 Vo2=VEE-IE*RE; // in volts
20 VB=VBB+IB*RB; // in volts
21 disp(Vo1, "Vo1 (V) =");
22 disp(Vo2, "Vo2 (V) =");
23 disp(VB, "Voltage at base (V) =")
24 disp("As base voltage, VB is 3.36 V and voltage at
      collector is -1.4 V, collector base junction is
     reverse biased. Thus the transistor is indeed in
```

### Scilab code Exa 4.7 pnp transistor

```
1 // Example 4.7: Value of RC to obtain VC = +5 V
2 clc, clear
3 betaf=50; // Current gain
4 disp("Let us assume that the transistor is in active
      region.");
5 disp("When current gain = 50")
6 VBE_active=-0.7; // in volts
7 // From Fig. 4.24
8 VC=5; // in volts
9 VEE=10; // in volts
10 RB=100e3; // in ohms
11 // Writing KVL for base circuit and putting Ic = F *
     Ib
12 IB=(VEE+VBE_active)/RB; // in amperes
13 IC=IB*betaf; // in amperes
14 RC=VC/IC; // in ohms
15 RC=RC*1e-3; // in kilo-ohms
16 disp(RC, "Value of RC to obtain VC = +5 V (k) =");
17 disp("When current gain = 100");
18 IC=IB*100; // in amperes
19 VC=IC*RC*1e3; // in volts
20 disp(VC, "Collector voltage (V) =");
21 disp("Since collector voltage is greater than the
     base voltage, the transistor goes into saturation
      as collector junction gets forward biased.");
```

Scilab code Exa 4.8 Solving a circuit with transistor

1 // Example 4.8: :Labelled voltages and currents

```
2 clc, clear
3 betaf=100; // Current gain
4 disp("Let us assume that the transistor is in active
      region.");
5 VBE_active=-0.7; // in volts
6 // From Fig. 4.25(a)
7 VCC=-10; // in volts
8 VEE=10; // in volts
9 RE=6.8e3; // in ohms
10 RC=10e3; // in ohms
11 R1=300e3; // in ohms
12 R2=180e3; // in ohms
13 // Applying Thevnin's theorem at point B
14 R_th=R1*R2/(R1+R2); // in ohms
15 V_th=VEE-(R2*(VEE-VCC)/(R1+R2)); // in volts
16 // From the Thevnin equivalent circuit in Fig. 4.25(
     b)
17 // Writing KVL for base-emitter circuit and putting
     Ic = F * Ib
18 IB=(VEE-V_th+VBE_active)/(R_th+(1+betaf)*RE); // in
     amperes
19 IB=IB*1e3; // in miliamperes
20 IC=betaf*IB; // in miliamperes
21 IE=IB+IC; // in miliamperes
22 VC=VCC+IC*RC*1e-3; // in volts
23 VE=VEE-IE*RE*1e-3; // in volts
24 VB=V_th+IB*R_th*1e-3; // in volts
25 I1=(VEE-VB)/R2; // in amperes
26 I1=I1*1e3; // in miliamperes
27 I2=I1+IB; // in miliamperes
28 disp(IC,"IC (mA) =");
29 disp(IE, "IE (mA) =");
30 disp(IB, "IB (mA) =");
31 disp(I1, "I1 (mA) =");
32 disp(I2, "I2 (mA) =");
33 disp(VC, "VC (V) =");
34 disp(VE, "VE (V) =");
35 disp(VB, "VB (V) =");
```
### Chapter 5

# **BJT** Biasing and Stability

Scilab code Exa 5.1 Fixed bias circuit

```
1 // Example 5.1: RB, RC

2 clc, clear

3 IB=40e-6; // in amperes

4 VCE=6; // in volts

5 VCC=12; // in volts

6 betaf=80;

7 VBE=0.7; // in volts

8 RB=(VCC-VBE)/IB; // in ohms

9 RC=(VCC-VCE)/(betaf*IB); // in ohms

10 RB=RB*1e-3; // in kilo-ohms

11 RC=RC*1e-3; // in kilo-ohms

12 disp(RB,"RB ( k ) =");

13 disp(RC,"RC ( k ) =");
```

Scilab code Exa 5.2 Determination of Q point

```
1 // Example 5.2: VCEQ, ICQ
2 clc, clear
```

```
3 VBE=0.7; // in volts
4 betaf=50;
5 // From Fig. 5.11(a)
6 VCC=18; // in volts
7 R1=82e3; // in ohms
8 R2=22e3; // in ohms
9 RC=5.6e3; // in ohms
10 RE=1.2e3; // in ohms
11 // Using Thevnin's theorem to obtain equivalent
      circuit given in Fig. 5.11(b)
12 VBB=R2*VCC/(R1+R2); // in volts
13 RB=R1*R2/(R1+R2); // in ohms
14 IB=(VBB-VBE)/(RB+(1+betaf)*RE); // in amperes
15 IC=betaf*IB; // in amperes
16 VCE=VCC-IC*(RC+RE)-IB*RE; // in volts
17 IC=IC*1e3; // in mili-amperes
18 disp(VCE, "VCEQ (V) =");
19 disp(IC, "ICQ (mA) =");
```

### Scilab code Exa 5.3 Self biased circuit

```
1 // Example 5.3: R1, R2, RC, RE
2 clc, clear
3 IC=1e-3; // in amperes
4 VCC=12; // in volts
5 betaf=100;
6 VBE=0.7; // in volts
7 // As suggested in the design constraints, allocate
1/3VCC to RC, another 1/3VCC to R2 leaving 1/3VCC
for VCEQ.
8 VB=4; // in volts
9 VE=VB-VBE; // in volts
10 // Neglecting base current,
11 RE=VE/IC; // in ohms
```

```
12 // Select the current through R1R2 equal to 0.1\,\mathrm{IC}
```

```
13 R1_plus_R2=VCC/(0.1*IC); // in ohms
14 R2=VB*R1_plus_R2/VCC; // in ohms
15 R1=R1_plus_R2-R2; // in ohms
16 RC=VCC/(3*IC); // in ohms
17 R1=R1*1e-3; // in kilo-ohms
18 R2=R2*1e-3; // in kilo-ohms
19 RC=RC*1e-3; // in kilo-ohms
20 RE=RE*1e-3; // in kilo-ohms
21 disp(R1,"R1 (k) =");
22 disp(R2,"R2 (k) =");
23 disp(RC,"RC (k) =");
```

Scilab code Exa 5.4 Amplifier circuit

```
1 // Example 5.4: VCEQ, ICQ
2 clc, clear
3 VBE=0.7; // in volts
4 betaf=45;
5 // From Fig. 5.14
6 VEE=9; // in volts
7 RB=100e3; // in ohms
8 RC=1.2e3; // in ohms
9 // Applying KVL in the clockwise direction base
     emitter loop
10 IB=(VEE-VBE)/RB; // in amperes
11 IC=betaf*IB; // in amperes
12 // Writing KVL for the collector loop
13 VCE=VEE-IC*RC; // in volts
14 IC=IC*1e3; // in mili-amperes
15 disp(VCE, "VCEQ (V) =");
16 disp(IC, "ICQ (mA) =");
```

Scilab code Exa 5.5 Determination of Q point

```
1 // Example 5.5: VCEQ, ICQ
2 clc, clear
3 VBE=0.7; // in volts
4 betaf=120;
5 // From Fig. 5.15
6 VCC=20; // in volts
7 VEE=20; // in volts
8 R1=8.2e3; // in ohms
9 R2=2.2e3; // in ohms
10 RC=2.7e3; // in ohms
11 RE=1.8e3; // in ohms
12\ //\ Using Thevnin's theorem to obtain equivalent
      circuit given in Fig. 5.16(b)
13 RB=R1*R2/(R1+R2); // in ohms
14 // From Fig. 5.16(a)
15 I = (VCC + VEE) / (R1 + R2); // in amperes
16 VBB=I*R2-VEE; // in volts
17 // Writing KVL for the base emitter loop and putting
      Ic= F * Ib gives
18 IB=(VEE+VBB-VBE)/(RB+(1+betaf)*RE); // in amperes
19 IC=betaf*IB; // in amperes
20 // KVL for the collector loop gives
21 VCE=VCC+VEE-IC*(RC+RE)-IB*RE; // in volts
22 IC=IC*1e3; // in mili-amperes
23 disp(VCE, "VCEQ (V) =");
24 disp(IC, "ICQ (mA) =");
```

#### Scilab code Exa 5.6 Amplifier circuit

```
1 // Example 5.6: RF so that IE=+2 mA
2 clc, clear
3 IE=2e-3; // in amperes
4 VBE=0.7; // in volts
```

```
5 betaf=49;
6 // From Fig. 5.17
7 VCC=12; // in volts
8 RB=25e3; // in ohms
9 RC=2e3; // in ohms
10 I1=VBE/RB; // in amperes
11 IB=IE/(1+betaf); // in amperes
12 // KVL for the indicated loop gives
13 RF=(VCC-RC*(I1+(1+betaf)*IB)-VBE)/(I1+IB); // in
ohms
14 RF=RF*1e-3; // in kilo-ohms
15 disp(RF, "RF so that IE=+2 mA ( k ) =");
```

Scilab code Exa 5.7 Amplifier circuit

```
1 // Example 5.7: RCQ, RE
2 clc, clear
3 VCEQ=3; // in volts
4 VBE=0.7; // in volts
5 betaf=200;
6 // From Fig. 5.18(a)
7 VCC=6; // in volts
8 VEE=6; // in volts
9 R1=90e3; // in ohms
10 R2=90e3; // in ohms
11 // Using Thevnin's theorem to obtain equivalent
      circuit given in Fig. 5.18(b)
12 RB=R1*R2/(R1+R2); // in ohms
13 VBB=R2*(VCC+VEE)/(R1+R2); // in volts
14 // In the output loop
15 x = VEE - VCEQ; // x = (IC+IB)RE in volts
16 // Applying KVL in the base emitter loop
17 IB = (VEE - VBE - x) / RB; // in amperes
18 IC=betaf*IB; // in amperes
19 // In the output loop
```

```
20 RC=VCC/IC; // in ohms
21 RE=x/(IC+IB); // in ohms
22 RC=RC*1e-3; // in kilo-ohms
23 RE=RE*1e-3; // in kilo-ohms
24 disp(RC,"RC ( k ) =");
25 disp(RE,"RE ( k ) =");
```

Scilab code Exa 5.8 Q point voltage

```
1 // Example 5.8: VCEQ
2 clc, clear
3 VBE=-0.7; // in volts
4 betaf=120;
5 // From Fig. 5.19(a)
6 VCC=18; // in volts
7 R1=47e3; // in ohms
8 R2=10e3; // in ohms
9 RC=2.4e3; // in ohms
10 RE=1.1e3; // in ohms
11 // Using Thevnin's theorem to obtain equivalent
     circuit given in Fig. 5.19(b)
12 VBB=R2*VCC/(R1+R2); // in volts
13 RB=R1*R2/(R1+R2); // in ohms
14 // Applying KVL in the base emitter loop and putting
      Ic = F * Ib
15 IB=(VBB+VBE)/(RB+(1+betaf)*RE); // in amperes
16 IC=betaf*IB; // in amperes
17 // In the collector emitter loop
18 VCE=-VCC+IC*(RC+RE)+IB*RE; // in volts
19 disp(VCE, "VCEQ (V) =");
```

Scilab code Exa 5.9 Stability factor

```
1 // Example 5.9 :(i) RB
2 //
                  (ii) Stability factor
3 //
                 (iii) IC at 100 C
4 clc, clear
5 bta=50;
6 VBE=0.7; // in volts
7 VCE=5; // in volts
8 // From Fig. 5.21
9 VCC=24; // in volts
10 RC=10e3; // in ohms
11 RE=500; // in ohms
12
13 disp("Part (i)");
14 // Applying KVL to the collector emitter circuit and
      putting Ic = F * Ib
15 IB=(VCC-VCE)/((RC+RE)*(bta+1)); // in amperes
16 IC=bta*IB; // at 25 C in amperes
17 RB=(VCE-VBE)/IB; // in ohms
18 RB=RB*1e-3; // in kilo-ohms
19 disp(RB, "RB (k) =")
20
21 disp("Part (ii)");
22 S=(1+bta)/(1+bta*(RC+RE)/(RC+RE+RB*1e3)); //
     Stability factor
23 disp(S, "Stability factor =");
24
25 disp("Part (iii)");
26 // From Table 5.1
27 del_ICO=(20-0.1)*1e-9; // in amperes
28 del_IC=S*del_ICO; // in amperes
29 IC=IC+del_IC; // at 100 C in amperes
30 IC=IC*1e3; // at 100 C in mili-amperes
31 disp(IC,"IC at 100 C (mA) =");
```

Scilab code Exa 5.10 Self bias circuit

```
1 // Example 5.10: (i) S(ICO) for RB/RE=10 and change
     in IC
2 //
                   (ii) S(VBE) for RB = 240 k, RE = 1
       k
           and change in IC
3 clc, clear
4 bta=100;
5
6 disp("Part (i)");
7 RB_RE=10; // RB/RE
8 S_ICO=(1+bta)*(1+RB_RE)/(1+bta+RB_RE);
9 // From Table 5.1
10 del_ICO=(20-0.1)*1e-9; // in amperes
11 del_IC=S_ICO*del_ICO; // in amperes
12 del_IC=del_IC*1e6; // in micro-amperes
13 disp(S_ICO, "S(ICO) for RB/RE=10");
14 disp(del_IC, "Change in IC ( A) =");
15
16 disp("Part (ii)");
17 RB=240e3; // in kilo-ohms
18 RE=1e3; // in kilo-ohms
19 S_VBE=-bta/(RB+(1+bta)*RE);
20 // From Table 5.1
21 del_VBE=0.48-0.65; // in volts
22 del_IC=S_VBE*del_VBE; // in amperes
23 del_IC=del_IC*1e6; // in micro-amperes
24 disp(S_VBE, "S(VBE) for (RB = 240 \text{ k}, RE = 1 \text{ k}) ="
     );
25 disp(del_IC, "Change in IC ( A ) =");
```

#### Scilab code Exa 5.11 Stability factor

1 // Example 5.11: S( ), IC at 100 C 2 clc, clear 3 IC=2e-3; // at 25 C in amperes 4 // From Table 5.1

```
5 bta1=50; // at 25 C
6 bta2=80; // at 100 C
7 RB_RE=10; // RB/RE
8 S=IC*(1+RB_RE)/(bta1*(1+bta2+RB_RE));
9 del_bta=bta2-bta1;
10 del_IC=S*del_bta; // in amperes
11 IC=IC+del_IC; // at 100 C in amperes
12 IC=IC*1e3; // at 100 C in mili-amperes
13 disp(S,"S() =");
14 disp(IC,"IC at 100 C (mA) =");
```

Scilab code Exa 5.12 Variation of collector current

```
1 // Example 5.12: Variation of IC over the
     temperature range -65 C to 175 C
2 clc, clear
3 RB_RE=2; // RB/RE
4 RE=4.7e3; // in ohms
5 IC=2e-3; // at 25 C in amperes
6 // From Table 5.1
7 bta=50; // at 25 C
8 S_ICO=(1+bta)*(1+RB_RE)/(1+bta+RB_RE);
9 S_VBE=-bta/(RE*(1+bta+RB_RE));
10 // From Table 5.1
11 bta1=20; // at -65 C
12 bta2=120; // at 175 C
13 S_bta1=IC*(1+RB_RE)/(bta*(1+bta1+RB_RE)); // For 25
       C to -65 C
14 S_bta2=IC*(1+RB_RE)/(bta*(1+bta2+RB_RE)); // For 25
       C to 175 C
15 // From Table 5.1
16
17 // For 25 C to -65 C
18 del_ICO=(0.2e-3-0.1)*1e-9; // in amperes
19 del_VBE=0.85-0.65; // in volts
```

```
20 del_bta=bta1-bta;
21 del_IC=S_ICO*del_ICO+S_VBE*del_VBE+S_bta1*del_bta;
     // in amperes
22 IC1=IC+del_IC; // at -65 C in amperes
23 IC1=IC1*1e3; // at -65 C in mili-amperes
24 disp(IC1,"IC at -65 C (mA) =");
25
26 // For 25 C to 175 C
27 del_ICO=(3.3e3-0.1)*1e-9; // in amperes
28 del_VBE=0.30-0.65; // in volts
29 del_bta=bta2-bta;
30 del_IC=S_ICO*del_ICO+S_VBE*del_VBE+S_bta2*del_bta;
     // in amperes
31 IC2=IC+del_IC; // at 175 C in amperes
32 IC2=IC2*1e3; // at 175 C in mili-amperes
33 disp(IC2,"IC at 175 C (mA) =");
```

Scilab code Exa 5.13 Current mirror

```
1 // Example 5.13: (i) R1
2 //
                   (ii) R1 for IC = 10 A
3 clc, clear
4 IC=1e-3; // in amperes
5 VCC=10; // in volts
6 bta=125;
7 VBE=0.7; // in volts
8
9 disp("Part (i)");
10 R1=bta*(VCC-VBE)/((bta+2)*IC); // in ohms
11 R1=R1*1e-3; // in kilo-ohms
12 disp(R1,"R1 ( k ) =");
13
14 disp("Part (i)");
15 IC=10e-6; // in amperes
16 R1=bta*(VCC-VBE)/((bta+2)*IC); // in ohms
```

```
17 R1=R1*1e-3; // in kilo-ohms
18 disp(R1,"R1 for (IC = 10 A) (k) =");
```

Scilab code Exa 5.14 Widlar current source

```
1 // Example 5.14: R1, RE
2 clc, clear
3 Io=10e-6; // in amperes
4 VCC=10; // in volts
5 bta=125;
6 VBE=0.7; // in volts
7 VT=25e-3; // in volts
8 // Let
9 I_ref=1e-3; // in amperes
10 R1=(VCC-VBE)/I_ref; // in ohms
11 R1=R1*1e-3; // in kilo-ohms
12 RE=VT*log(I_ref/Io)/((1+1/bta)*Io); // in ohms
13 RE=RE*1e-3; // in kilo-ohms
14 disp(R1,"R1 ( k ) =");
15 disp(RE,"RE ( k ) =");
```

Scilab code Exa 5.15 Current Repeaters

```
1 // Example 5.11: IC1, IC2, IC3
2 clc, clear
3 bta=125;
4 VBE=0.7; // in volts
5 VT=25e-3; // Voltage equivalent to temperatue at
    room temperature in volts
6 // From Fig. 5.27
7 VC=9; // in volts
8 RC=30; // in kilo-ohms
9 RE=1.94; // in kilo-ohms
```

#### Scilab code Exa 5.16 Output current

```
1 // Example 5.16: Io
2 clc, clear
3 bta=100;
4 VBE=0.7; // in volts
5 // From Fig. 5.30
6 // Writing KVL for the indicated loop
7 I_ref=(10-VBE)/10; // in mili-amperes
8 Io=bta*I_ref/(2*(1+bta)); // in mili-amperes
9 disp(Io,"Io (mA) =");
```

### Scilab code Exa 5.17 Current mirror

```
1 // Example 5.17: (i) IC1 and IC2
2 // (ii) RC so that Vo = 6 V
3 clc, clear
4 bta=200;
5 // From Fig. 5.31
6
7 disp("Part (i)");
8 I_ref=(12-0.7)/15; // in amperes
```

```
9 I1=0.7/2.8; // in amperes
10 IC=(I_ref-I1)*bta/(bta+2); // in mili-amperes
11 disp(IC,"IC1 (mA) =");
12 disp(IC,"IC2 (mA) =");
13
14 disp("Part (ii)");
15 Vo=6; // in volts
16 RC=(12-Vo)/IC; // in kilo-ohms
17 disp(RC,"RC so that (Vo = 6 V) (k) =");
```

Scilab code Exa 5.18 Modified current mirror

```
1 // Example 5.18: Emitter current in transistor Q3
2 clc, clear
3 bta=100;
4 VBE=0.75; // in volts
5 // From Fig. 5.32
6 I=(10-VBE)/4.7; // in mili-amperes
7 IE=I/2; // in mili-amperes
8 disp(IE,"Emitter current in transistor Q3 (mA) =");
```

### Chapter 6

# **BJT** Ampilifiers

Scilab code Exa 6.2 Bipolar Junction Transistor

```
1 // Example 6.2: r , gm

2 clc, clear

3 IBQ=7.6e-6; // in amperes

4 bta=104;

5 VT=25e-3; // Voltage equivalent to temperatue at

room temperature in volts

6 ICQ=IBQ*bta; // in amperes

7 gm=ICQ/VT; // in ampere per volt

8 gm=gm*1e3; // in mili-ampere per volt

9 r_pi=bta/gm; // in kilo-ohms

10 disp(r_pi,"r (k) =");

11 disp(gm,"gm (mA/V) =");
```

#### Scilab code Exa 6.3 Hybrid h parameter model

```
1 // Example 6.3: AI, Ri, AV, AVs, Ro, Ro'
2 clc, clear
3 hie=1e3; // in ohms
```

```
4 hfe=100;
5 hre=2e-4;
6 hoe=20e-6; // in amperes per volt
7 RC=5e3; // in ohms
8 Rs=1e3; // in ohms
9 // From Table 6.3
10 AI = -hfe/(1+hoe*RC);
11 Ri=hie+hre*AI*RC; // in ohms
12 AV=AI*RC/Ri;
13 AVs=AV*Ri/(Ri+Rs);
14 Yo=hoe-hfe*hre/(hie+Rs); // in ohms inverse
15 Ro=1/Yo; // in ohms
16 Ro_dash=Ro*RC/(Ro+RC); // in ohms
17 Ri=Ri*1e-3; // in kilo-ohms
18 Ro=Ro*1e-3; // in kilo-ohms
19 Ro_dash=Ro_dash*1e-3; // in kilo-ohms
20 disp(AI, "AI =");
21 disp(Ri, "Ri (k) =");
22 disp(AV, "AV =");
23 disp(AVs, "AVs =");
24 disp(Ro, "Ro (k) = ");
25 disp(Ro_dash, "Ro'' (k) =");
```

Scilab code Exa 6.4 Bipolar Junction Transistor

```
1 // Example 6.4: AI', AVs, Ri, eff, Ro, Ro'
2 clc, clear
3 hie=2e3; // in ohms
4 hfe=50;
5 hre=2e-4;
6 hoe=20e-6; // in amperes per volt
7 // From Fig. 6.22(a)
8 Rs=2e3; // in ohms
9 R1=90e3; // in ohms
10 R2=10e3; // in ohms
```

```
11 RC=5e3; // in ohms
12 // From the Table 6.3
13 RB=R1*R2/(R1+R2); // in ohms
14 AI = -hfe/(1+hoe*RC);
15 Ri=hie+hre*AI*RC; // in ohms
16 Ri_eff=RB*Ri/(RB+Ri); // in ohms
17 AI_dash=AI*RB/(RB+Ri);
18 AVs=AI*RC*Ri_eff/(Ri*(Rs+Ri_eff));
19 Rs_eff=Rs*RB/(Rs+RB); // in ohms
20 Yo=hoe-hfe*hre/(hie+Rs_eff); // in ohms inverse
21 Ro=1/Yo; // in ohms
22 Ro_dash=Ro*RC/(Ro+RC); // in ohms
23 Ri_eff=Ri_eff*1e-3; // in kilo-ohms
24 Ro=Ro*1e-3; // in kilo-ohms
25 Ro_dash=Ro_dash*1e-3; // in kilo-ohms
26 disp(AI_dash, "AI'' =");
27 disp(AVs, "AVs =");
28 disp(Ri_eff, "Ri, eff (k) =");
29 disp(Ro, "Ro (k) = ");
30 disp(Ro_dash, "Ro'' (k) =");
```

Scilab code Exa 6.5 Simplified h parameter model

```
1 // Example 6.5: AI, AVs, Ri, Ro'

2 clc, clear

3 hie=4e3; // in ohms

4 hfe=200;

5 // From Fig. 6.27(a)

6 Rs=5e3; // in ohms

7 R1=90e3; // in ohms

8 R2=10e3; // in ohms

9 RC=5e3; // in ohms

10 RE=1e3; // in ohms

11 // From Fig 6.27(b)

12 RB=R1*R2/(R1+R2); // in ohms
```

```
13 Ri=hie+(1+hfe)*RE; // in ohms
14 Ri_eff=RB*Ri/(RB+Ri); // in ohms
15 AI=-hfe*RB/(RB+Ri);
16 AVs=-hfe*RC*Ri_eff/(Ri*(Rs+Ri_eff));
17 Ro_dash=RC; // in ohms
18 Ri=Ri*1e-3; // in kilo-ohms
19 Ro_dash=Ro_dash*1e-3; // in kilo-ohms
20 disp(AI, "AI =");
21 disp(AVs, "AVs =");
22 disp(Ri, "Ri (k) =");
23 disp(Ro_dash, "Ro'' (k) =");
```

Scilab code Exa 6.6 Hybrid pi model

```
1 // Example 6.6: AI, Ri, AVs
2 clc, clear
3 bta=100;
4 VBE=0.7; // Cut-in voltage in volts
5 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
6 // From Fig. 6.33
7 RB=100e3; // in ohms
8 RC=3e3; // in ohms
9 VBB=3; // in volts
10
11 // DC analysis
12 // From dc equivalent circuit in Fig. 6.34(a)
13 IBQ=(VBB-VBE)/RB; // in amperes
14 ICQ=bta*IBQ; // in amperes
15 gm=ICQ/VT; // in ampere per volt
16 r_pi=bta/gm; // in ohms
17
18 // AC analysis
19 // From ac equivalent circuit using approximate
     hybrid – model in Fig. 6.34(b)
```

```
20 AI=-bta;
21 Ri=RB+r_pi; // in ohms
22 AVs=-bta*RC/(RB+r_pi);
23 Ri=Ri*1e-3; // in kilo-ohms
24 disp(AI, "AI =");
25 disp(Ri, "Ri (k) =");
26 disp(AVs, "AVs =");
```

Scilab code Exa 6.7 CC amplifier

```
1 // Example 6.7: (a) Load resistance RE to make Ri
          500 k
2 //
                   (b) AV, Ro, Ro'
3 clc, clear
4 IC=2e-3; // in amperes
5 Rs=5e3; // Source resistance in ohms
6 bta=125;
7 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
8
9 disp("Part (a)");
10 Ri=500e3; // in ohms
11 gm=IC/VT; // in mho
12 r_pi=bta/gm; // in ohms
13 RE=(Ri-r_pi)/(1+bta); // in ohms
14 REk=RE*1e-3; // in kilo-ohms
15 disp(REk, "RE (k) = ");
16
17 disp("Part (b)");
18 AV = (1+bta) * RE/(Rs+Ri);
19 Ro=(Rs+r_pi)/(1+bta); // in ohms
20 Ro_dash=Ro*RE/(Ro+RE); // in ohms
21 disp(Ro, "Ro ( ) =");
22 disp(Ro_dash, "Ro'' () =");
```

### Scilab code Exa 6.8 Voltage gain

```
1 // Example 6.8: Ri, AVs
2 clc, clear
3 IC=0.2e-3; // in amperes
4 bta=125;
5 Rs=2e3; // in ohms
6 RE=100; // in ohms
7 RC=5e3; // in ohms
8 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
9 gm=IC/VT; // in mho
10 r_pi=bta/gm; // in ohms
11 Ri=r_pi+(1+bta)*RE; // in ohms
12 AVs=-bta*RC/(Rs+r_pi+(1+bta)*RE);
13 Ri=Ri*1e-3; // in kilo-ohms
14 disp(Ri,"Ri (k) =");
15 disp(AVs, "AVs =");
```

Scilab code Exa 6.9 Hybrid pi model

```
1 // Example 6.9: r , AI, Ri, AVs, Ro, Ro'
2 clc, clear
3 bta=200;
4 VT=25e-3; // Voltage equivalent to temperatue at
room temperature in volts
5 // From Fig. 6.39
6 VBE=0.7; // Cut-in voltage in volts
7 VCC=9; // in volts
8 RB=200e3; // in ohms
9 RC=2e3; // in ohms
10
```

```
11 // DC analysis
12 // From dc equivalent circuit in Fig. 6.40(a)
13 // Writing KVL from collector to base loop
14 IB=(VCC-VBE)/(RB+(1+bta)*RC); // in amperes
15 ICQ=bta*IB; // in amperes
16 gm=ICQ/VT; // in mho
17 r_pi=bta/gm; // in ohms
18
19 // AC analysis
20 // From ac equivalent circuit using Miller's theorem
      in Fig. 6.40(b)
21 // Assuming AV >> 1
22 RL=RB*RC/(RB+RC); // Effective load resistance in
     ohms
23 // Using hybrid – model and approximate resulta
     given in Table 6.5 for CE amplifier stage, we
     have
24 AI=-bta;
25 AV=-bta*RL/r_pi;
26 Ro=%inf;
27 r_pi=r_pi*1e-3; // in kilo-ohms
28 RL=RL*1e-3; // in kilo-ohms
29 disp(r_pi," r ( k ) =");
30 disp(AI, "AI =");
31 disp(AV, "AVs =");
32 disp(Ro, "Ro =");
33 disp(RL, "Ro'' (k) =");
```

### Scilab code Exa 6.10 re model

```
1 // Example 6.10: Ri, eff, Ro, AV, AI
2 clc, clear
3 bta=200;
4 ro=50e3; // in ohms
5 VBE=0.7; // Cut-in voltage in volts
```

```
6 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
7 // From Fig. 6.44
8 VCC=16; // in volts
9 R1=90e3; // in ohms
10 R2=10e3; // in ohms
11 RC=2.2e3; // in ohms
12 RE=0.68e3; // in ohms
13
14 // DC analysis
15 // From the Thevnin's equivalent circuit in Fig.
      6.45(a)
16 RB=R1*R2/(R1+R2); // in ohms
17 VBB=VCC*R2/(R1+R2); // in volts
18 // From the base loop
19 IB=(VBB-VBE)/(RB+(1+bta)*RE); // in amperes
20 IE=(1+bta)*IB; // in amperes
21 re=VT/IE; // in ohms
22
23 // AC analysis
24 Ri=bta*re+(1+bta)*RE; // in ohms
25 Ri_eff=RB*Ri/(RB+Ri); // in ohms
26 AI=-bta*RB/(RB+bta*(re+RE));
27 \quad AV = -RC / RE;
28 Ri_eff=Ri_eff*1e-3; // in kilo-ohms
29 disp(Ri_eff, "Ri, eff (k) =");
30 disp(%inf, "Ro =");
31 disp(AI, "AI =");
32 disp(AV, "AVs =");
```

# Chapter 7

# Field Effect Transistors Characteristics and Biasing

Scilab code Exa 7.1 Transfer curve of FET

```
1 // Example 7.1: Transfer curve
2 clc, clear
3 IDSS=12; // in mili-amperes
4 VP=-5; // in volts
5 // Plotting transfer curve
6 VGS=[0:-0.01:VP]; // Gate source voltage in volts
7 // Using Shockley's equation
8 ID=IDSS*(1-VGS/VP)^2; // Drain current in mili-
amperes
9 plot(VGS,ID);
10 xtitle("Transfer Curve","VGS (V)","ID (mA)");
```

Scilab code Exa 7.2 NMOS transistor



Figure 7.1: Transfer curve of FET

```
1 // Example 7.2: (a) Region of operation
2 //
                   (b) Region of operation
3 //
                   (c) Region of operation
4 clc, clear
5 VT=2; // in volts
6 VGS=3; // in volts
7 disp(VGS-VT, "VGS - VT (V)");
8
9 disp("Part (a)");
10 disp(0.5, "VDS (V) =");
11 disp("Since VDS < VGS - VT, therefore transistor is
      in ohmic region.");
12
13 disp("Part (b)");
14 disp(1, "VDS (V) =");
15 disp("Since VDS = VGS - VT, therefore transistor is
      in saturation region.");
16
17 disp("Part (c)");
```

Scilab code Exa 7.3 n channel JFET

```
1 // Example 7.3: IDQ, VDSQ
2 clc, clear
3 IDSS=12; // in mili-amperes
4 VP=-4; // in volts
5 // From Fig. 7.28
6 VDD=12; // in volts
7 RD=1.2; // in kilo-ohms
8 // Since IG=0
9 VGS=-1.5; // in volts
10 // Using Shockley's equation
11 ID=IDSS*(1-VGS/VP)^2; // Drain current in mili-
amperes
12 VDS=VDD-ID*RD; // in volts
13 disp(ID, "IDQ (mA) =");
14 disp(VDS, "VDSQ (V) =");
```

Scilab code Exa 7.4 Self bias configuration

```
1 // Example 7.4: VDSQ, IDSQ, VD, VS
2 clc, clear
3 IDSS=6e-3; // in amperes
4 VP=-6; // in volts
5 // From Fig. 7.31
6 VDD=12; // in volts
7 RD=2.2e3; // in ohms
```



Figure 7.2: Self bias configuration

```
8 RS=1.6e3; // in ohms
9 // Plotting transfer characteristics
10 VGS=[0:-0.01:VP]; // Gate source voltage in volts
11 // Using Shockley's equation
12 ID=IDSS*(1-VGS/VP)^2; // Drain current in amperes
13 ID=ID*1e3; // Drain current in mili-amperes
14 plot(VGS, ID);
15 xtitle("Transfer Characteristics", "VGS (V)", "ID (mA)
     ");
16 // Plotting bias line
17 // From gate source circuit
18 ID=-VGS/RS; // Source current in amperes
19 ID=ID*1e3; // Source current in mili-amperes
20 plot(VGS, ID, "RED");
21 // Intersection of transfer characteristics with the
      bias curve
22 // Putting VGS = -ID*RS in Shockley's equation and
     solving, we get ID^2*RS^2 + (2*RS*VP - VP^2/IDSS)
     *ID + VP^2
```



Figure 7.3: Operating point

Scilab code Exa 7.5 Operating point

```
1 // Example 7.5: Operating point
2 clc, clear
3 VP=-5; // in volts
4 IDSS=12e-3; // in amperes
5 // From Fig. 7.34(a)
6 VDD=18; // in volts
7 R1=400; // in kilo-ohms
8 R2=90; // in kilo-ohms
9 RD=2e3; // in ohms
10 RS=2e3; // in ohms
11 // Applying Thevnin's theorem to obtain simplified
      circuit in Fig. 7.34(b)
12 VGG=VDD*R2/(R1+R2); // in volts
13 // Plotting transfer characteristics
14 VGS=[VGG:-0.01:VP]; // Gate source voltage in volts
15 // Using Shockley's equation
16 ID=IDSS*(1-VGS/VP)^2; // Drain current in amperes
17 ID=ID*1e3; // Drain current in mili-amperes
18 plot2d(VGS,ID,rect=[-5,0,3,12]);
19 xtitle("Transfer Characteristics", "VGS (V)", "ID (mA)
     ");
20 // Plotting bias line
21 // From the KVL for the gate-loop
22 ID=(-VGS+VGG)/RS; // Source current in amperes
23 ID=ID*1e3; // Source current in mili-amperes
24 plot(VGS, ID, "RED");
25 // Intersection of transfer curve with the bias
      curve
  // Putting VGS = VGG-ID*RS in Shockley's equation
26
     and solving, we get
  // ID<sup>2</sup>*RS<sup>2</sup> + (2*RS*VP - 2*VGG*RS - VP<sup>2</sup>/IDSS)*ID +
27
      (VGG-VP)^2
28 // Solving the equation
29 p_eq = poly([(VGG-VP)^2 (2*RS*VP-2*VGG*RS-VP^2/IDSS)
       RS<sup>2</sup>], "x", "coeff");
30 p_roots = roots(p_eq);
```



Figure 7.4: n channel enhancement type MOSFET

```
31 IDQ=p_roots(1); // in amperes
32 // Writing the KVL for the drain source loop
33 VDSQ=VDD-IDQ*(RD+RS); // in volts
34 IDQ=IDQ*1e3; // in mili-amperes
35 disp(VDSQ, "VDSQ (V) =");
36 disp(IDQ, "IDQ (mA) =");
```

Scilab code Exa 7.6 n channel enhancement type MOSFET

```
1 // Example 7.6: VDSQ, IDQ
2 clc, clear
3 ID=6e-3; // in amperes
4 VGS=8; // in volts
5 VT=3; // in volts
6 // From Fig. 7.37(a)
```

```
7 VDD=12; // in volts
8 RD=2e3; // in ohms
9 // Plotting transfer curve
10 k=ID/(VGS-VT)^2; // in amperes per volt square
11 VGS=[3:0.01:VDD]; // Gate source voltage in volts
12 ID=k*(VGS-VT)^2; // Drain current in amperes
      .... (i)
13 ID=ID*1e3; // Drain current in mili-amperes
14 plot(VGS, ID);
15 xtitle("Transfer Curve", "VGS (V)", "ID (mA)");
16 // Plotting bias line
17 // From the simplified dc equivalent circuit in Fig.
       7.37(b)
18 VGS=[0:0.01:VDD]; // Gate source voltage in volts
19 ID=(VDD-VGS)/RD; // Source current in amperes
20 ID=ID*1e3; // Source current in mili-amperes
21 plot(VGS, ID, "RED");
22 // Intersection of transfer curve with the bias
      curve
23 // Putting VGS = VDD-ID*RD in equation (i) and
     solving, we get ID<sup>2</sup>*RD<sup>2</sup> + (2*RD*VT - 2*VDD*RD -
      1/k + ID + (VDD-VT)<sup>2</sup>
24 // Solving the equation
25 p_eq = poly([(VDD-VT)^2 (2*RD*VT-2*VDD*RD-1/k) RD
      ^2],"x","coeff");
26 p_roots= roots(p_eq);
27 IDQ=p_roots(1); // in amperes
28 VGSQ=VDD-IDQ*RD; // in volts
29 IDQ=IDQ*1e3; // in mili-amperes
30 disp(VGSQ, "VDSQ (V) =");
31 disp(IDQ, "IDQ (mA) =");
```

Scilab code Exa 7.7 Operating point of MOSFET



Figure 7.5: Operating point of MOSFET

```
1 // Example 7.7: IDQ, VDSQ, VGSQ
2 clc, clear
3 ID=5e-3; // in amperes
4 VGS=6; // in volts
5 VT=3; // in volts
6 // From Fig. 7.39(a)
7 VDD=24; // in volts
8 R1=10; // in mega-ohms
9 R2=6.8; // in mega-ohms
10 RD=2.2e3; // in ohms
11 RS=0.75e3; // in ohms
12 // Applying Thevnin's theorem to obtain simplified
     circuit in Fig. 7.39(b)
13 VGG=VDD*R2/(R1+R2); // in volts
14 // Plotting transfer characteristics
15 k=ID/(VGS-VT)^2; // in amperes per volt square
16 VGS=[3:0.01:VGG]; // Gate source voltage in volts
17 ID=k*(VGS-VT)^2; // Drain current in amperes
      .... (i)
```

```
18 ID=ID*1e3; // Drain current in mili-amperes
19 plot(VGS,ID);
20 xtitle("Transfer Characteristics", "VGS (V)", "ID (mA)
      ");
21 // Plotting bias line
22 VGS=[0:0.01:VGG]; // Gate source voltage in volts
23 // Writing KVL for the gate-source loop
24 ID=(VGG-VGS)/RS; // Source current in amperes
25 ID=ID*1e3; // Source current in mili-amperes
26 plot(VGS, ID, "RED");
27 // Intersection of transfer curve with the bias
      curve
28 // Putting VGS = VGG-ID*RD in equation (i) and
      solving, we get ID^2*RS^2 + (2*RS*VT - 2*VGG*RS - 2*VGG*RS)
       1/k + ID + (VGG-VT)<sup>2</sup>
29 // Solving the equation
30 \text{ p_eq} = \text{poly}([(VGG-VT)^2 (2*RS*VT-2*VGG*RS-1/k) RS)]
      ^2],"x","coeff");
31 p_roots = roots(p_eq);
32 IDQ=p_roots(1); // in amperes
33 VGSQ=VGG-IDQ*RS; // in volts
34 // From the output circuit
35 VDSQ=VDD-IDQ*(RD+RS); // in volts
36 IDQ=IDQ*1e3; // in mili-amperes
37 disp(IDQ, "IDQ (mA) =");
38 \text{ disp}(VDSQ, "VDSQ (V) =");
39 disp(VGSQ, "VGSQ (V) =");
```

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# Chapter 8

# **FET Amplifiers**

Scilab code Exa 8.1 Transconductance

```
1 // Example 8.1: gm
2 clc, clear
3 IDSS=12; // in mili-amperes
4 Vp=-5; // in volts
5 VGS=-1.5; // in volts
6 gmo=2*IDSS/abs(Vp); // in mili-Siemens
7 gm=gmo*(1-VGS/Vp); // in mili-Siemens
8 disp(gm,"gm (mS) =");
```

Scilab code Exa 8.2 Fixed bias CS amplifier

```
1 // Example 8.2: Voltage gain
2 clc, clear
3 gm=2; // in mili-ampere per volt
4 rd=10; // in kilo-ohms
5 // From Fig. 8.7
6 RD_eff=10*10/(10+10); // in kilo-ohms
7 AV=-gm*rd*RD_eff/(rd+RD_eff); // Voltage gain
8 disp(AV,"Voltage gain =");
```

Scilab code Exa 8.3 Self bias CS amplifier

```
1 // Example 8.3: gm, , Ri, Ro, AV
2 clc, clear
3 VGSQ=-2.6; // in volts
4 IDSS=8; // in mili-amperes
5 Vp=-6; // in volts
6 rd=50; // in kilo-ohms
7 // From Fig. 8.11
8 RD=3.3; // in kilo-ohms
9 RG=1; // in mega-ohms
10 RS=1; // in kilo-ohms
11 gmo=2*IDSS/abs(Vp); // in mili-ampere per volt
12 gm=gmo*(1-VGSQ/Vp); // in mili-ampere per volt
13 mu=rd*gm; //
14 Ro=(rd+(1+mu)*RS)*RD/(RD+rd+(1+mu)*RS); // in kilo-
     ohms
15 AV = -mu * RD / (RD + rd + (1 + mu) * RS);
16 disp(gm, "gm (mA/V) =");
17 disp(mu," =");
18 disp(RG, "Ri (M) = ");
19 disp(Ro,"Ro ( k ) =");
20 disp(AV, "AV =");
```

Scilab code Exa 8.4 JFET source follower

```
1 // Example 8.4: AV, Ri, Ro
2 clc, clear
3 IDSS=16; // in mili-amperes
4 Vp=-4; // in volts
5 rd=40; // in kilo-ohms
```

```
6 // From Fig. 8.14
7 RS=2.2; // in kilo-ohms
8 // Using dc analysis
9 VGSQ=-2.8; // in volts
10 gmo=2*IDSS/abs(Vp); // in mili-ampere per volt
11 gm=gmo*(1-VGSQ/Vp); // in mili-ampere per volt
12 mu=rd*gm; // Amplification factor
13 AV=mu*RS/(rd+(1+mu)*RS);
14 Ri=10; // in mega-ohms
15 Ro=rd*RS/(rd+(1+mu)*RS); // in kilo-ohms
16 disp(AV, "AV =");
17 disp(Ri, "Ri (M ) =");
18 disp(Ro, "Ro (k ) =");
```

Scilab code Exa 8.5 Common gate JFET amplifier

```
1 // Example 8.5: AV, Ri, Ro
2 clc, clear
3 VGSQ=-1.8; // in volts
4 rd=40; // in kilo-ohms
5 IDSS=8; // in mili-amperes
6 Vp=-2.8; // in volts
7 // From Fig. 8.16
8 RD=3.3; // in kilo-ohms
9 RS=1.5; // in kilo-ohms
10 gmo=2*IDSS/abs(Vp); // in mili-Siemens
11 gm=gmo*(1-VGSQ/Vp); // in mili-Siemens
12 mu=rd*gm; // Amplification factor
13 AV = (1 + mu) * RD / (rd + RD);
14 Ri_dash=(RD+rd)/(1+mu); // in kilo-ohms
15 Ri=Ri_dash*RS/(Ri_dash+RS); // in kilo-ohms
16 Ro=rd*RD/(rd+RD);
17 disp(AV, "AV =");
18 disp(Ri, "Ri (k) =");
19 disp(Ro, "Ro (k) = ");
```

### Scilab code Exa 8.6 E MOSFET amplifier

```
1 // Example 8.6: gm, Ri, Ro, AV
2 clc, clear
3 VGSQ=8; // in volts
4 VT=3; // in volts
5 k=0.3e-3;
6 // From Fig. 8.18
7 RF=10e6; // in ohms
8 RD=2.2e3; // in ohms
9 gm=2*k*(VGSQ-VT); // in Siemens
10 Ri=RF/(1+gm*RD); // in ohms
11 Ro=RF*RD/(RF+RD); // in ohms
12 AV = -gm * Ro;
13 gm=gm*1e3; // in mili-Siemens
14 Ri=Ri*1e-6; // in mega-ohms
15 Ro=Ro*1e-3; // in kilo-ohms
16 disp(gm, "gm (mS) =");
17 disp(AV, "AV =");
18 disp(Ri,"Ri (M) =");
19 disp(Ro, "Ro (k) = ");
```
## Chapter 9

# **Multistage Amplifiers**

Scilab code Exa 9.1 CE CC configuration

```
1 // Exmaple 9.1: Overall voltage gain, Overall
     current gain
2 clc, clear
3 bta=100;
4 r_pi=0.5; // in kilo-ohms
5 // From Fig. 9.4
6 Rs=2; // in kilo-ohms
7 RC=2; // in kilo-ohms
8 RE=5; // in kilo-ohms
9 // As the first stage is a CE amplifier stage
10 AV1=-bta*RC/(Rs+r_pi); // Voltage gain of first
     amplifier
11 // The second stage is a CC amplifier
12 AV2=(1+bta)*RE/(Rs+r_pi+(1+bta)*RE); // Voltage gain
      of second amplifier
13 AV=AV1*AV2; // Overall voltage gain
14 AI=Rs*AV/RE; // Overall current gain
15 disp(AV, "Overall voltage gain =");
16 disp(AI, "Overall current gain =");
```

### Scilab code Exa 9.2 Two stage amplifier

```
1 // Example 9.2: Overall voltage gain, Current gain,
     Input impedance, Output impedance
2 clc, clear
3 bta=100;
4 VBE=0.7; // in volts
5 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
6 // From Fig. 9.7
7 R1=22; // in kilo-ohms
8 R2=3.3; // in kilo-ohms
9 RC1=6; // in kilo-ohms
10 RE1=0.5; // in kilo-ohms
11 R3=16; // in kilo-ohms
12 R4=6.2; // in kilo-ohms
13 RC2=2; // in kilo-ohms
14 RE2=1; // in kilo-ohms
15 RL=10; // in kilo-ohms
16
17
18 // DC analysis
19
20 // From simplified dc equivalent circuit for stage 1
      in Fig. 9.8(a)
21 RB1=R1*R2/(R1+R2); // in kilo-ohms
22 VBB1=15*R2/(R1+R2); // in volts
23 IB1=(VBB1-VBE)/(RB1+(1+bta)*RE1); // in mili-amperes
24 IC1=bta*IB1; // in mili-amperes
25 gm1=IC1/VT; // in mili-Siemens
26 r_pi1=bta/gm1; // in kilo-ohms
27
28 // From simplified dc equivalent circuit for stage 2
      in Fig. 9.8(b)
```

```
29 RB2=R3*R4/(R3+R4); // in kilo-ohms
30 VBB2=15*R4/(R3+R4); // in volts
31 IB2=(VBB2-VBE)/(RB2+(1+bta)*RE2); // in mili-amperes
32 IC2=bta*IB2; // in mili-amperes
33 gm2=IC2/VT; // in mili-Siemens
34 r_pi2=bta/gm2; // in kilo-ohms
35
36
37 // AC analysis
38
39 // Applying Thevnin theorem at 1-1' in ac equivalent
      circuit in Fig. 9.9 to obtain equivalent circuit
      of stage 1 in Fig. 9.10(a)
40 RL1=RC1*RB2/(RC1+RB2); // Effective load for first
     stage in kilo-ohms
41 AV1=-bta*RL1/r_pi1; // Voltage gain of first stage
42
43 // Using the Thevnin's equivalent of first stage the
      equivalent circuit of second stage is shown in
     Fig. 9.10(b)
44 RL2=RC2*RL/(RC2+RL); // Effective load for second
     stage in kilo-ohms
45 AV2=-bta*RL2/(RL1+r_pi2); // Voltage gain of second
     stage
46
47 Io_Ic2=-RC2/(RC2+RL); // Io/Ic2
48 Ic2_Ib2=-bta; // Ic2/Ib2
49 //From simplified diagram in Fig. 9.11
50 Ib2_Ic1=-RL1/(RL1+r_pi2); // Ib2/Ic1
51 Ic1_Ib1=-bta; // Ic1/Ib1
52 Ib1_Ii=RB1/(RB1+r_pi1); // Ib1/Ii
53
54 AV=AV1*AV2; // Overall voltage gain
55 AI=Io_Ic2*Ic2_Ib2*Ib2_Ic1*Ic1_Ib1*Ib1_Ii; // Overall
      current gain
56 Ri=RB1*r_pi1/(RB1+r_pi1); // Input impedance in kilo
     -ohms
57 Ro=RC2*RL/(RC2+RL); // Output impedance in kilo-ohms
```

```
58 disp(AV, "Overall voltage gain =");
59 disp(AI, "Overall current gain =");
60 disp(Ri, "Imput impedance (k) =");
61 disp(Ro, "Output impedance (k) =");
```

Scilab code Exa 9.3 CC CE composite pair

```
1 // Example 9.3: Voltage gain
2 clc, clear
3 bta=150;
4 VA=130; // in volts
5 IC=100; // in micro-amperes
6 Rs=50; // in kilo-ohms
7 RC=250; // in kilo-ohms
8 VT=25; // Voltage equivalent to temperatue at room
     temperature in mili-volts
9 gm=IC/VT; // in mili-Siemens
10 ro=VA/IC; // in Megaohms
11 ro=ro*1e3; // in kilo-ohms
12 r_pi=bta/gm; // in kilo-ohms
13 // From ac equivalent circuit of the first CC stage
     using hybrid – model in Fig. 9.13(a)
14 // Voltage gain of CC stage
15 AV1=(1+bta)*ro/(Rs+r_pi+(1+bta)*ro); // Voltage gain
      of first stage
16 Ro1=(Rs+r_pi)/(1+bta); // in kilo-ohms
17 Ro1_dash=ro*Ro1/(ro+Ro1); // in kilo-ohms
18 // From the ac equivalent circuit of second stage in
      Fig. 9.13(b)
19 RL=ro*RC/(ro+RC); // Effective load for second stage
      in kilo-ohms
20 AV2=-bta*RL/(Ro1_dash+r_pi); // Voltage gain of
     second stage
21 AV=AV1*AV2; // Overall voltage gain
22 disp(AV, "Voltage gain =");
```

## Scilab code Exa 9.4 FET cascade

```
1 // Example 9.4: (i) Voltage gain, Input impedance,
     Output impedance
2 //
                  (ii) Output voltage
3 clc, clear
4 gm=2.5; // in mili-Siemens
5 // From Fig. 9.14(a)
6 RG=3; // in Mega-ohms
7 RD=2.2; // in kilo-ohms
8
9 disp("Part (i)");
10 AV1=-gm*RD; // Voltage gain of both individual
     stages
11 AV=AV1^2; // Overall voltage gain
12 disp(AV, "Voltage gain =");
13 disp(RG, "Input impedance (M) =");
14 disp(RD, "Output impedance (k) =");
15
16 disp("Part (ii)");
17 Vi=10; // in mili-volts
18 RD_dash=RD*10/(RD+10); // Effective load of secong
     stage in kilo-ohms
19 // Now the gain of second stage
20 AV2=-gm*RD_dash;
21 AV=AV1*AV2; // Overall voltage gain
22 Vo=Vi*AV; // Output voltage in mili-volts
23 disp(Vo, "Output voltage (mV) =");
```

Scilab code Exa 9.5 Three stage amplifier

```
1 // Example 9.5: (i) Gain of each stage
2 //
                  (ii) Overall voltage gain
3 //
                 (iii) Output resistance Ro'
4 clc, clear
5 gm=1 // in mili-mho
6 rd=40; // in kilo-ohms
7 // From Fig. 9.14(b)
8 RD1=40 // in kilo-ohms
9 RS1=2 // in kilo-ohms
10 RD2=10 // in kilo-ohms
11 RS3=5 // in kilo-ohms
12 mu=rd*gm; // Amplification factor
13
14 disp("Part (i)");
15 AV1=-mu*RD1/(rd+RD1+(1+mu)*RS1); // Voltage gain of
      first stage (CS amplifier with RS1)
16 AV2=-mu*RD2/(rd+RD2); // Voltage gain of second
      stage (CS amplifier stage)
17 AV3=mu*RS3/(rd+(1+mu)*RS3); // Voltage gain of third
      stage (CD amplifier stage)
18
  disp(AV1, "Voltage gain of first stage (CS amplifier
     with RS1) =");
  disp(AV2, "Voltage gain of second stage (CS amplifier
19
      stage) =");
20 disp(AV3," Voltage gain of third stage (CD amplifier
     stage) =");
21
22 disp("Part (ii)");
23 AV=AV1*AV2*AV3; // Overall voltage gain
24 disp(AV, "Overall voltage gain =");
25
26 disp("Part (iii)");
27 // Last stage is a CD amplifier, therefore
28 Ro=rd/(1+mu); // in kilo-ohms
29 Ro_dash=Ro*RS3/(Ro+RS3); // in kilo-ohms
30 disp(Ro_dash, "Output resistance (k) =");
```

Scilab code Exa 9.6 FET and BJT cascade

```
1 // Example 9.6: Input impedance, Output impedance,
     Voltage gain
2 clc, clear
3 gm=2.5; // in mili-Siemens
4 r_pi=1.3; // in kilo-ohms
5 bta=200;
6 // From Fig. 9.14(c)
7 Ri2=15*4.7*1.3/(15*4.7+15*1.3+4.7*1.3); // Input
     impedance of second stage in kilo-ohms
8 RD_dash=1.8*Ri2/(1.8+Ri2); // Effective load for the
      first stage in kilo-ohms
9 AV1=-gm*RD_dash; // Voltage gain of the loaded 1st
     stage
10 AV2=-bta*2.7/r_pi; // Voltage gain of the 2nd stage
11 AV=AV1*AV2; // Overall voltage gain
12 disp(10, "Input impedance (M) =");
13 disp(2.7, "Output impedance (k) = ");
14 disp(AV, "Voltage gain =");
```

Scilab code Exa 9.7 Darlington emitter follower

```
1 // Example 9.7: AV, Ri, Ro
2 clc, clear
3 RE=0.5; // in kilo-ohms
4 Rs=50; // in kilo-ohms
5 Ic1=15e-3; // in mili-amperes
6 Ic2=1; // in mili-amperes
7 VA=100; // in volts
8 bta=150;
```

```
9 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
10 // For Q1
11 gm1=Ic1/VT; // in mili-mho
12 r_pi1=bta/gm1; // in kilo-ohms
13 ro1=VA/Ic1; // in kilo-ohms
14 // For Q2
15 gm2=Ic2/VT; // in mili-mho
16 r_pi2=bta/gm2; // in kilo-ohms
17 ro2=VA/Ic2; // in kilo-ohms
18 // From ac equivalent circuit in Fig. 9.17
19 RE2=ro2*RE/(ro2+RE); // Effective load for stage Q2
     in kilo-ohms
20 Ri2=r_pi2+(1+bta)*RE2; // Input resistance for
     second stage in kilo-ohms
21 AV2=(1+bta)*RE2/Ri2; // Voltage gain of the second
     stage
22 RE1=ro1*Ri2/(ro1+Ri2); // Effective load for the
     first stage in kilo-ohms
23 Ri1=r_pi1+(1+bta)*RE1; // Input resistance for first
      stage in kilo-ohms
24 AV1=(1+bta)*RE1/Ri1; // Voltage gain of first stage
25 AV=AV1*AV2; // Overall voltage gain
26 Ro=ro2*(r_pi2+ro1)/(ro2*(1+bta)+r_pi2+ro1); //
     Output resistance in kilo-ohms
27 Ri1=Ri1*1e-3; // in Mega-ohms
28 disp(AV, "AV =");
29 disp(Ri1, "Ri (M) =");
30 disp(Ro, "Ro (k) = ");
```

### Scilab code Exa 9.8 Cascode circuit

```
1 // Example 9.8:Gain
2 clc, clear
3 IC=1; // in mili-amperes
```

4 bta=120;

- 5 VT=25e-3; // Voltage equivalent to temperatue at room temperature in volts
- 6 // From Fig. 9.20
- 7 RC=6; // in kilo-ohms
- 8 AV1=-1; // Voltage gain of CE stage (from Eqn. 9.35)
- 9 gm=IC/VT; // in mili-mho
- 10 AV2=gm\*RC; // Voltage gain of CB stage
- 11 AV=AV1\*AV2; // Overall voltage gain
- 12 disp(AV, "Gain =");

# Chapter 10

# Frequency Response of Amplifiers

## Scilab code Exa 10.1 Bode plots

```
1 // Example 10.1: Asymptotic magnitude and phase
      response curves
2 clc, clear
3 w = [0:70];
4 // Asymptotic magnitude response curve
5 for i=1:length(w)
6
       a(i)=32;
7
       if w(i) <10 then
            b(i)=0;
8
            c(i)=0;
9
10
        elseif w(i) <50</pre>
11
            b(i) = 14*(w(i) - 10)/40;
12
            c(i) = 0;
13
        else
14
            b(i) = 20 * \log 10 (w(i) / 10);
```



Figure 10.1: Bode plots



Figure 10.2: Bode plots

```
15
            c(i) = -20 * \log 10 (w(i) / 50);
16
        end
17 end
18 A=a+b+c;
19 plot2d(w, A, rect = [0, 0, 70, 50]);
20 xtitle("Asymptotic magnitude response curve"," (rad
      /sec)","20 log |A(j)| in dB");
21 // Asymptotic phase response curve
22 scf(1);
23 w = [1:600];
24 for i=1:length(w)
       if w(i)<1 then</pre>
25
26
            theta1(i)=0;
        elseif w(i)<5</pre>
27
28
            theta1(i)=31.45*(w(i)-1)/4;
29
            theta2(i)=0;
        elseif w(i) <100</pre>
30
31
            theta1(i) = 45 * \log 10 (w(i) / 10);
32
            theta2(i) = -45 * log10(w(i)/50);
        elseif w(i) <500</pre>
33
34
            theta1(i)=90;
            theta2(i) = -58.55 - 31.45 * (w(i) - 100) / 400;
35
36
        else
37
            theta1(i)=90;
            theta2(i) = -90;
38
39
        end
40 \text{ end}
41 theta=theta1+theta2;
42 plot(w,theta);
43 xtitle("Asymptotic phase curve response"," (rad/sec
      )"," ()")
```



Figure 10.3: Bode plots



Figure 10.4: Bode plots

Scilab code Exa 10.2 Bode plots

```
1 // Example 10.2: Bode's plots
2 clc, clear
3 w = [0:0.1:8];
4 // Asymptotic magnitude response curve
5 for i=1:length(w)
        a(i)=40;
6
7
        if w(i) < 1.3 then
8
             b(i) = 20 * w(i);
9
             c(i) = 0;
             d(i) = 0;
10
11
             e(i)=0;
12
        elseif w(i)<3</pre>
13
             b(i) = 20 * w(i);
             c(i) = 20*(w(i) - 1.3);
14
15
             d(i) = 0;
             e(i)=0;
16
        elseif w(i) <6</pre>
17
18
             b(i) = 20 * w(i);
19
             c(i) = 20 * (w(i) - 1.3);
20
             d(i) = -20*(w(i) - 3);
21
             e(i)=0;
22
        else
23
             b(i)=20*w(i);
24
             c(i) = 20 * (w(i) - 1.3);
25
             d(i) = -20 * (w(i) - 3);
26
             e(i) = -20*(w(i) - 6);
27
        end
28 \text{ end}
29 \quad A=a+b+c+d+e;
30 plot2d(w,A,rect=[0,0,7,200]);
31 xtitle("Amplitude (Gain) |A(j)| in dB", "log "," |
      A(j) | dB");
32 // Asymptotic phase response curve
33 scf(1);
34 for i=1:length(w)
        thetab=90;
35
```

```
36
        if w(i) < 0.3 then
37
            thetac(i)=0;
38
            thetad(i)=0;
39
            thetae(i)=0;
40
        elseif w(i)<2</pre>
            thetac(i) = 45*(w(i) - 0.3);
41
42
            thetad(i)=0;
            thetae(i)=0;
43
        elseif w(i) <2.3</pre>
44
            thetac(i) = 45 * (w(i) - 0.3);
45
            thetad(i) = -45*(w(i)-2);
46
            thetae(i)=0;
47
48
        elseif w(i)<4</pre>
            thetac(i) = 90;
49
            thetad(i) = -45*(w(i)-2);
50
51
            thetae(i)=0;
        elseif w(i)<5</pre>
52
            thetac(i) = 90;
53
            thetad(i)=-90;
54
55
            thetae(i)=0;
        elseif w(i)<7</pre>
56
            thetac(i) = 90;
57
            thetad(i) = -90;
58
            thetae(i) = -45*(w(i)-5);
59
60
        else
61
            thetac(i) = 90;
62
            thetad(i)=-90;
            thetae(i) = -90;
63
64
        end
65 end
66 theta=thetab+thetac+thetad+thetae;
67 plot(w,theta);
                      ( ) in degrees", "log10 ", " ( )"
68 xtitle("Phase
      )
```

Scilab code Exa 10.3 Pole of transfer function

```
1 // Example 10.3: CS, Zero frequency
2 clc, clear
3 gm=1e-3; // in mho
4 fL=10; // in hertz
5 // From Fig. 10.10
6 RS=6e3; // in ohms
7 I=RS/(1+RS*gm); // Impedance seen by CS in ohms
8 CS=1/(2*%pi*fL*I); // in farads
9 CS=CS*1e6; // in micro-farads
10 disp(CS, "CS ( F) =");
11 disp("Here at f = 0 Hz, CS has infinite reactance.")
;
12 disp("Therefore, zero frequency fzero = 0 Hz here, i
.e. the voltage transfer function is zero at DC."
);
```

Scilab code Exa 10.4 Low frequency response

Scilab code Exa 10.5 Single pole model

```
1 // Example 10.5: C
2 clc, clear
3 IC=1e-3; // in amperes
4 b_o=120;
5 b_jw=10;
6 f=25e6; // in hertz
7 C_mu=1e-12; // in farads
8 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
9 wb=sqrt((2*%pi*f)^2*b_jw^2/(b_o^2-b_jw^2)); // in
     rad/sec
10 wT=wb*b_o; // in hertz
11 gm=IC/VT; // in mho
12 C_pi=gm/wT-C_mu; // in farads
13 C_pi=C_pi*1e12; // in pico-farads
14 disp(C_pi," C (pF) =");
```

Scilab code Exa 10.7 Upper half power frequency

```
1 // Example 10.7: (a) Midband gain, Upper half-power
     frequency
2 / /
                    (b) Zi
3 clc, clear
4 ICQ=1e-3; // in amperes
5 RS=300; // in ohms
6 RC=1.2e3; // in ohms
7 bta=125;
8 fT=300e6; // in hertz
9 C_mu=0.5e-12; // in farads
10 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
11
12 disp("Part (a)");
13 gm=ICQ/VT; // in mho
14 r_pi=bta/gm; // in ohms
```

```
15 // To find C_pi
16 C_pi=gm/(2*%pi*fT)-C_mu; // in farads
17 AVo=-bta*RC/(RS+r_pi); // Midband gain
18 disp(AVo, "Midband gain =");
19 R_pi0=RS*r_pi/(RS+r_pi);
20 a1=R_pi0*C_pi+(R_pi0+RC*(1+gm*R_pi0))*C_mu; // in
     seconds
21 a2=R_pi0*RC*C_pi*C_mu; // in seconds
22 p1=1/a1; // in rad/sec
23 p2=a1/a2; // in rad/sec
24 disp(p2/p1,"p2/p1 =");
25 disp("Since p2/p1 >> 8, therefore dominant-pole
     approximation holds good.");
26 wH=p1*1e-6; // in M rad/sec
27 disp(wH, "Upper half-power frequency (M rad/sec) =");
28
29 disp("Part (b)");
30 CM=C_pi+C_mu*(1+gm*RC); // in farads
31 Zi=r_pi/(1+%i*wH*1e6*CM*r_pi); // in ohms
32 disp(Zi, "Zi ( ) =");
```

Scilab code Exa 10.12 Dominant pole approximation

```
1 // Example 10.12: (a) Approximate value of fH
2 // (b) Approximate location of the
      closest non-dominant pole
3 clc, clear
4 RS=600; // in ohms
5 RC1=1.5e3; // in ohms
6 RC2=600; // in ohms
7 r_pi1=1.2e3; // in ohms
8 gm1=0.1; // in mho
9 C1=24.5e-12; // in farads
10 C_pi1=C1; // in farads
11 C2=0.5e-12; // in farads
```

```
12 C_mu1=C2; // in farads
13 r_pi2=2.4e3; // in ohms
14 gm2=0.05; // in mho
15 C3=19.5e-12; // in farads
16 C_pi2=C3; // in farads
17 C4=0.5e-12; // in farads
18 C_mu2=C4; // in farads
19
20 function[c]=parallel(a,b)
21
       c=a*b/(a+b);
22 endfunction
23
24 disp("Part (a)");
25 R11_0=parallel(RS,r_pi1); // in ohms
26 R33_0=parallel(RC1,r_pi2); // in ohms
27 R22_0=R11_0*(1+gm1*R33_0)+R33_0; // in ohms
28 R44_0=R33_0*(1+gm2*RC2)+RC2; // in ohms
29 a1=R11_0*C1+R22_0*C2+R33_0*C3+R44_0*C4; // in
      seconds
30 fH=1/(2*%pi*a1); // in hertz
31 fH=fH*1e-6; // in Mega-hertz
32 \text{ disp(fH,"fH (MHz) =");}
33
34 disp("Part (b)");
35 R33_1=R33_0; // in ohms
36 R44_1=R44_0; // in ohms
37 // From Fig. 10.61(a)
38 R22_1=R33_0; // in ohms
39 // From Fig. 10.61(b)
40 R44_3=RC2; // in ohms
41 // From Fig. 10.61(c)
42 R33_2=parallel(parallel(r_pi2,RC2),parallel(1/gm1,
     R11_0));
43 R44_2=R33_2*(1+gm2*RC2)+RC2; // in ohms
44 a2=R11_0*C1*R22_1*C2+R11_0*C1*R33_1*C3+R11_0*C1*
     R44_1*C4+R22_0*C2*R33_2*C3+R22_0*C2*R44_2*C4+
     R33_0*C3*R44_3*C4; // in seconds
45 p2=a1/a2;
```

```
126
```

Scilab code Exa 10.13 Cascode amplifier

```
1 // Example 10.13: (a) fH for cascode amplifier
2 //
                     (b) fH for common -emitter stage
3 clc, clear
4 RC1=1.5e3; // in ohms
5 RC2=RC1;
6 RS=300; // in ohms
7 r_pi=2e3; // in ohms
8 gm=0.05; // in mho
9 bta=100;
10 C_pi=19.5e-12; // in farads
11 C_mu=0.5e-12; // in farads
12
13 disp("Part (a)");
14 R_pi1=RS*r_pi/(RS+r_pi); // in ohma
15 Ri2=r_pi/(1+bta); // in ohms
16 RL1=RC1*Ri2/(RC1+Ri2); // in ohms
17 a11=R_pi1*C_pi+(R_pi1*(1+gm*RL1)+RL1)*C_mu; // in
     seconds
18 a12=C_pi/gm+C_mu*RC2; // in seconds
19 a1=a11+a12; // in seconds
20 fH=1/(2*%pi*a1); // in hertz
21 fH=fH*1e-6; // in Mega-hertz
22 disp(fH,"fH for cascode amplifier (MHz) =");
23
24 disp("Part (b)");
25 a1=R_pi1*C_pi+(R_pi1*(1+gm*RC1)+RC1)*C_mu; // in
     seconds
26 fH=1/(2*%pi*a1); // in hertz
```

```
27 fH=fH*1e-6; // in Mega-hertz
28 disp(fH,"fH for common-emitter stage (MHz) =");
```

Scilab code Exa 10.15 Capacitances of transistor

```
1 // Example 10.15: (a) CB and CL
2 //
                     (b) Zero introduced by CE
3 clc, clear
4 RE=1.5e3; // in ohms
5 Rs=600; // in ohms
6 bta=100;
7 r_pi=1e3; // in ohms
8 fL=50; // in hertz
9
10 disp("Part (a)");
11 fLB=fL/2; // in hertz
12 fLE=fLB; // in hertz
13 CB=1/(2*%pi*fLB*(Rs+r_pi)); // in farads
14 CB=CB*1e6; // in micro-farads
15 function[c]=parallel(a,b)
16
       c=a*b/(a+b);
17 endfunction
18 CE=1/(2*%pi*fLE*parallel(RE,(Rs+r_pi)/(1+bta))); //
     in farads
19 CE=CE*1e6; // in micro-farads
20 disp(CB, "CB ( F ) =");
21 disp(CE, "CE ( F) =");
22
23 disp("Part (b)");
24 fE=1e6/(2*%pi*RE*CE); // in hertz
25 disp(fE, "fE (Hz) =");
```

Scilab code Exa 10.16 Common emitter stage

```
1 // Example 10.16: AVo, fH
2 clc, clear
3 RC=1.5e3; // in ohms
4 Rs=0.6e3; // in ohms
5 // From Fig. 10.69
6 C_pi=19.5e-12; // in farads
7 r_pi=1e3; // in ohms
8 C_mu=0.5e-12; // in farads
9 gm=0.1; // in mho
10 bta=r_pi*gm;
11 AVo=-bta*RC/(Rs+r_pi);
12 R_pi=Rs*r_pi/(Rs+r_pi); // in ohms
13 R_mu=R_pi+(1+gm*R_pi)*RC; // in ohms
14 a1=R_pi*C_pi+R_mu*C_mu; // in seconds
15 a2=R_pi*C_pi*R_mu*C_mu; // in seconds
16 p2_pi=a1^2/a2; // p2/p1
17 disp("Since p2/pi >> 8, therefore dominant-pole
      approximation holds good.");
18 fH=1/(2*%pi*a1); // in hertz
19 fH=fH*1e-6; // in Mega-hertz
20 disp(AVo, "AVo =");
21 disp(fH, "fH (MHz) =");
```

### Scilab code Exa 10.17 Time constant method

```
1 // Example 10.17: (b) a1, a2
2 clc, clear
3 RS=0.3e3; // in ohms
4 r_pi=2e3; // in ohms
5 RC=0.6; // in ohms
6 gm=0.1e-3; // in mho
7 C_pi=19.5e-12; // in farads
8 C_mu=0.5e-12; // in farads
9 R_pi=RS*r_pi/(RS+r_pi); // in ohms
10 a1=C_pi*R_pi+C_mu*(R_pi+RC+gm*R_pi*RC); // in
```

```
seconds
11 a1=a1*1e9; // in nano-seconds
12 a2=C_pi*R_pi*C_mu*RC; // in seconds square
13 disp(a1,"a1 (ns) =");
14 disp(a2,"a2 (sec square) =");
```

Scilab code Exa 10.18 Gain bandwidth product

```
1 // Example 10.18: Upper 3 dB frequency
2 clc, clear
3 r_pi1=1.4e3; // in ohms
4 r_pi2=2.8e3; // in ohms
5 gm1=0.15; // in mho
6 gm2=0.05; // in mho
7 C_pi1=20e-12; // in farads
8 C_pi2=25e-12; // in farads
9 C_mu1=0.5e-12; // in farads
10 C_mu2=C_mu1 // in farads
11 bta1=gm1*r_pi1;
12 bta2=gm2*r_pi2;
13 // From Fig. 10.71
14 RS=600; // in ohms
15 RC1=1.5e3; // in ohms
16 RL2=600; // in ohms
17 // From ac model in Fig. 10.72
18 R_pi1=RS*r_pi1/(RS+r_pi1); // in ohms
19 RL1=RC1*r_pi2/(RC1+r_pi2); // in ohms
20 R_mu1=R_pi1+RL1+gm1*RL1*R_pi1; // in ohms
21 R_pi2=RL1; // in ohms
22 R_mu2=R_pi2+RL2+gm2*RL2*R_pi2; // in ohms
23 all=C_pil*R_pil+C_mul*R_mul; // in seconds
24 a12=C_pi2*R_pi2+C_mu2*R_mu2; // in seconds
25 a1=a11+a12; // in seconds
26 fH1=1/(2*%pi*a11); // in hertz
27 fH2=1/(2*%pi*a12); // in hertz
```

```
28 fH=1/(2*%pi*a1); // in hertz
29 fH1=fH1*1e-6; // in Mega-hertz
30 fH2=fH2*1e-6; // in Mega-hertz
31 fH=fH*1e-6; // in Mega-hertz
32 AV1=-bta1*RC1/(RS+r_pi1); // Gain of first stage
33 AV2=-bta2*RL2/(RC1+r_pi2); // Gain of second stage
34 AV=AV1*AV2; // Gain of cascade
35 disp(fH, "Upper 3 dB frequency (MHz) =");
36 disp("Bandwidth:");
37 disp(fH1, "Stage 1 only (MHz) =");
38 disp(fH2, "Stage 2 only (MHz) =");
39 disp(fH, "Cascade (MHz) =");
40 disp("Gain:");
41 disp(abs(AV1), "Stage 1 only =");
42 disp(abs(AV2), "Stage 2 only =");
43 disp(AV, "Cascade =");
44 disp("Gain-bandwidth product:");
45 disp(fH1*abs(AV1)*1e6, "Stage 1 only (MHz) =");
46 disp(fH2*abs(AV2)*1e6, "Stage 2 only (MHz) =");
47 disp(fH*AV*1e6, "Cascade (MHz) =");
```

Scilab code Exa 10.19 Approximation of fH

```
1 // Example 10.19: Approximate value of fH

2 clc, clear

3 btaf=150;

4 VA=120; // in volts

5 fT=400e6; // in hertz

6 C_mu=0.5e-12; // in farads

7 ICQ=100e-6; // in amperes

8 RS=50e3; // in ohms

9 RC=250e3; // in ohms

10 VT=25e-3; // Voltage equivalent to temperatue at

room temperature in volts

11 gm=ICQ/VT; // in mho
```

```
12 r_pi=btaf/gm; // in ohms
13 ro=VA/ICQ; // in ohms
14 C_pi=btaf/(2*%pi*fT*r_pi)-C_mu; // in farads
15 function[c]=parallel(a,b)
16
       c=a*b/(a+b);
17 endfunction
18 // From AC model in Fig. 10.73
19 Ri=r_pi+(1+btaf)*parallel(ro,r_pi); // in ohms
20 R_mu1=parallel(RS,Ri); // in ohms
21 // From Fig. 10.75(b)
22 R=(50+36.36)/(1+145); // in ohms
23 R_pi1=parallel(r_pi,R); // in ohms
24 R_pi2=parallel(r_pi,parallel((RS+r_pi)/(1+btaf),ro))
     ; // in ohms
25 RL=parallel(ro,RC); // in ohms
26 R_mu2=R_pi2*(1+gm*RL)+RL; // in ohms
27 a1=R_mu1*C_mu+R_pi1*C_pi+R_pi2*C_pi+R_mu2*C_mu; //
     in seconds
28 fH=1/(2*%pi*a1); // in hertz
29 fH=fH*1e-3; // in kilo-hertz
30 disp(fH, "Approximate value of fH (kHz) =");
```

Scilab code Exa 10.20 Low and high 3 dB frequency

```
1 // Example 10.20: (a) Low 3 dB frequency
2 // (b) High 3 dB frequency
3 clc, clear
4 // From Fig. 10.76
5 C_gd1=2e-12; // in farads
6 C_gs1=5e-12; // in farads
7 gm1=10e-3; // in mho
8 C1=1e-6; // in farads
9 C_gd2=2e-12; // in farads
10 C_gs2=5e-12; // in farads
11 gm2=10e-3; // in mho
```

```
12 C2=10e-6; // in farads
13 // From low-frequency equivalent cicuit in Fig.
      10.77
14 RS=0.2e3; // in ohms
15 RG1=50e3; // in ohms
16 RS1=0.25e3; // in ohms
17 RS2=0.15e3; // in ohms
18 RD2=5e3; // in ohms
19 R=10e3; // in ohms
20 C3=5.3e-6; // in farads
21
22 function[c]=parallel(a,b)
23
       c=a*b/(a+b);
24 endfunction
25
26 disp("Part (a)");
27 // From low-frequency equivalent cicuit in Fig.
      10.77
28 tau1=C1*(RS+RG1); // in seconds
29 R_22=RD2+R; // in ohms
30 tau2=C2*R_22; // in seconds
31 R_33=parallel(RS2,1/gm2); // in ohms
32 tau3=C3*R_33; // in ohms
33 fL=(1/tau1+1/tau2+1/tau3)/(2*%pi); // in hertz
34 disp(fL, "Low 3 dB frequency (Hz) =");
35
36 disp("Part (b)");
37 // From high frequency equivalent cicuit in Fig.
      10.78
38 R_gd1=parallel(RS,RG1); // in ohms
39 // From Fig. 10.79
40 R_gs1=(R_gd1+RS1)/(1+gm1*RS1); // in ohms
41 R_gs2=parallel(RS1,1/gm2); // in ohms
42 R_gd2=R_gs2+parallel(RD2,R)+R_gs2*parallel(RD2,R)*
     gm2; // in ohms
43 a1=C_gd1*R_gd1+C_gs1*R_gs1+C_gs2*R_gs2+C_gd2*R_gd2;
     // in seconds
44 fH=1/(2*%pi*a1); // in hertz
```

```
133
```

```
45 fH=fH*1e-6; // in Mega-hertz
46 disp(fH,"High 3 dB frequency (MHz) =");
```

Scilab code Exa 10.21 Dominant pole approximation

```
1 // Example 10.21: (a) AVo, Approximate value of fH
2 / /
                     (b) Frequency of the nearest non-
     dominant pole
3 clc, clear
4 gm=le-3; // in mho
5 Rd=40e3; // in ohms
6 Cgs=5e-12; // in farads
7 Cgd=1e-12; // in farads
8 Cds=1e-12; // in farads
9
10 function[c]=parallel(a,b)
11
       c=a*b/(a+b);
12 endfunction
13
14 disp("Part (a)");
15 RS=5e3; // in ohms
16 RD1=40e3; // in ohms
17 RD2=10e3; // in ohms
18 // From AC model of cascade amplifier in Fig. 10.80
19 Rds1=40e3; // in ohms
20 Rds2=40e3; // in ohms
21 R11_0=RS; // in ohms
22 RL1=parallel(Rds1,RD1); // in ohms
23 R22_0=RS+RL1+gm*RS*RL1; // in ohms
24 R33_0=RL1; // in ohms
25 RL2=parallel(Rds2,RD2); // in ohms
26 R44_0=RL1+RL2+gm*RL1*RL2; // in ohms
27 R55_0=RL2; // in ohms
28 Cl=Cgs; // in farads
29 C2=Cgd; // in farads
```

```
30 C3=Cds+Cgs; // in farads
31 C4=Cds; // in farads
32 C5=Cds; // in farads
33 a1=C1*R11_0+C2*R22_0+C3*R33_0+C4*R44_0+C5*R55_0; //
      in seconds
34 fH=1/(2*%pi*a1); // in hertz
35 fH=fH*1e-6; // in Mega-hertz
36 \quad \text{AVo} = \text{gm} * \text{RL1} * \text{gm} * \text{RL2};
37 disp(AVo, "AVo =");
38 disp(fH, "Approximate value of fH (MHz) =");
39
40 disp("Part (b)");
41 R22_1=RL1; // in ohms
42 R33_1=RL1; // in ohms
43 R44_1=R44_0; // in ohms
44 R55_1=RL2; // in ohms
45 R33_2=parallel(RL1,parallel(1/gm,RS)); // in ohms
46 R44_2=R33_2+RL2+gm*R33_2*RL2; // in ohms
47 R55_2=R55_0; // in ohms
48 R44_3=RL2; // in ohms
49 R55_3=RL2; // in ohms
50 R55_4=parallel(RL1,parallel(1/gm,RL2)); // in ohms
51 a2=R11_0*C1*(R22_1*C2+R33_1*C3+R44_1*C4+R55_1*C5)+
      R22_0*C2*(R33_2*C3+R44_2*C4+R55_2*C5)+R33_0*C3*(
      R44_3*C4+R55_3*C5)+R44_0*C4*R55_4*C5; // in
      seconds
52 p2=a1/a2;
53 f=p2/(2*%pi); // in hertz
54 f=f*1e-6; // in Mega-hertz
55 disp(f,"Frequency of the nearest non-dominant pole (
     MHz) = ");
```

Scilab code Exa 10.23 Time constant method

1 // Example 10.23: Value of fH for the cascade

```
2 clc, clear
3 bta=100;
4 r_pi1=0.5e3; // in ohms
5 r_pi2=0.5e3; // in ohms
6 r_pi3=1e3; // in ohms
7 fT=200e6; // in hertz
8 C_mu=1e-12; // in farads
9 // From Fig. 10.85
10 RS=2e3; // in ohms
11 RE1=5e3; // in ohms
12 RC2=2e3; // in ohms
13 RC3=1e3; // in ohms
14 RE3=100; // in ohms
15
16 function[c]=parallel(a,b)
       c=a*b/(a+b);
17
18 endfunction
19
20 // From Fig. 10.86
21 Ro1=parallel(RE1,(RS+r_pi1)/(1+bta)); // in ohms
22 gm2=bta/r_pi2; // in mho
23 gm3=bta/r_pi3; // in mho
24 C_pi2=bta/(2*%pi*fT*r_pi2)-C_mu; // in farads
25 C_pi3=bta/(2*%pi*fT*r_pi3)-C_mu; // in farads
26
27 // From Fig. 10.87
28 C1=C_pi2; // in farads
29 C2=C_mu; // in farads
30 C3=C_pi3; // in farads
31 C4=C_mu; // in farads
32 R11_0=parallel(Ro1,r_pi1); // in ohms
33 RL1=parallel(RC2,r_pi3+(1+bta)*RE3); // in ohms
34 R22_0=R11_0+RL1*(1+gm2*R11_0); // in ohms
35
36 // From Fig. 10.88
37 R_dash=2.1e3/(1+10); // in ohms
38 R33_0=parallel(RC2,R_dash); // in ohms
39
```

## Chapter 11

## **Feedback Amplifiers**

Scilab code Exa 11.1 Feedback network

```
1 // Example 11.1: Open-loop gain, Return ratio,
     Reverse transmission
                              of feedback circuit
2 clc, clear
3 // Let A be open-loop gain and B be return ratio
4 // For A, B 10% higher, -1.1A + 55.11B = -50.1
5 // For A, B 10% lower, -0.9A + 44.91B = -49.9
6 // Solving the two equations
7 a=[-1.1 55.11; -0.9 44.91];
8 b = [-50.1; -49.9];
9 c=inv(a)*b;
10 A=c(1,1);
11 B=c(2,1);
12 disp(A, "Open-loop gain =");
13 disp(B, "Return ratio =");
14 disp(B/A," Reverse transmission of the feedback
      circuit =");
```

Scilab code Exa 11.2 Amount of feedback

```
1 // Example 11.2: Necessary amount of feedback, Gain
     without feedback
2 clc, clear
3 // Let A be gain without feedback and b be necessary
      amount of feedback
4 // AOL can assume values A, 1.1A, 0.9A, i.e. 10\%
      variation
5 // For AOL = 1.1A yields, 50.01 + 1.1A(50.01b - 1) =
6 // When AOL = 0.9A, 49.99 + 0.9A(49.99b - 1) = 0
7 // Solving the two equations
8 a=[1.1*50.01 -1.1; 0.9*44.99 -0.9];
9 b = [-50.01; -49.99];
10 c=inv(a)*b;
11 d=c(1,1); // A*b
12 A=c(2,1);
13 b=d/A;
14 disp(b," Necessary amount of feedback =");
15 disp(A, "Gain without feedback =");
```

### Scilab code Exa 11.3 Second harmonic distortion

```
1 // Example 11.3: (a) Output voltage
2 // (b) Input voltage
3 clc, clear
4 B1=36; // Fundamental output in volts
5 B2=7*B1/100; // Second-harmonic distortion in volts
6 Vs=0.028; // Input in volts
7 A=B1/Vs; // Gain
8
9 disp("Part (a)");
10 b=1.2/100; // Amount of feedback in volts
11 B1f=B1/(1+b*A); // Fundamental output with feedback
in volts
12 B2f=B2/(1+b*A); // Second-harmonic distortion with
```

Scilab code Exa 11.4 Closed loop parameters

```
1 // Example 11.4: Closed loop parameters
2 clc, clear
3 Av = 1000;
4 bta=0.01;
5 Zin=1; // in kilo-ohms
6 Zo=420; // in ohms
7 fL=1.5; // in kilo-hertz
8 fH=501.5; // in kilo-hertz
9 disp("Closed loop parameters :");
10 T=Av*bta; // Return ratio
11 // From Fig. 11.18
12 Af=Av/(1+T); // Closed loop gain
13 Zif=Zin*(1+T); // Closed loop input impedance in
     kilo-ohms
14 Zof=Zo/(1+T); // Closed loop output impedance in
     ohms
15 fLf=fL/(1+T); // Closed loop lower 3 dB frequency in
      kilo-hertz
16 fHf=fH*(1+T); // Closed loop upper 3 dB frequency in
```

```
kilo-hertz
17 disp(Af, "Gain =");
18 disp(Zif, "Input impedance (k) =");
19 disp(Zof, "Output impedance () =");
20 disp(fLf, "Lower 3 dB frequency (kHz) =");
21 disp(fHf, "Upper 3 dB frequency (kHz) =");
```

Scilab code Exa 11.5 Noise reduction

```
1 // Example 11.5: Output signal voltage, Output noise
      voltage, Improvement in S/N ratio
2 clc, clear
3 A1=1;
4 Vs=1; // in volts
5 Vn=1; // in volts
6 \quad A2 = 100;
7 bta=1;
8 Vos=Vs*A1*A2/(1+bta*A1*A2); // Output signal voltage
      in volts
9 Von=Vn*A1/(1+bta*A1*A2); // Output noise voltage in
      volts
10 SNRi=20*log10(Vs/Vn); // Input S/N ratio in dB
11 SNRo=20*log10(Vos/Von); // Output S/N ratio in dB
12 SNR=SNRo-SNRi; // Improvement in S/N raio in dB
13 disp(Vos, "Output signal voltage (V) =");
14 disp(Von, "Output noise voltage (V) =");
15 disp(SNR, "Improvement in S/N ratio (dB) =");
```

Scilab code Exa 11.6 Non inverting configuration

```
1 // Example 11.6: (b) R2/R1
2 // (c) Amount of feedback in decibels
3 // (d) Vo, Vf, Vi
```

```
(e) Decrease in Af
4 //
5 clc, clear
6
7 disp("Part (b)");
8 \quad A = 1 \, e 4;
9 Af=10;
10 bta=(A/Af-1)/A; // Feedback factor
11 R2_R1=1/bta-1; // R2/R1
12 disp(R2_R1, "R2/R1 =");
13
14 disp("Part (c)");
15 dB=20*log10(1+A*bta); // Amount of feedback in
      decibels
16 disp(dB, "Amount of feedback (dB) =");
17
18 disp("Part (d)");
19 Vs=1; // in volts
20 Vo=Af*Vs; // in volts
21 Vf=bta*Vo; // in volts
22 Vi=Vs-Vf; // in volts
23 disp(Vo, "Vo (V) =");
24 disp(Vf, "Vf (V) =");
25 disp(Vi, "Vi (V) =");
26
27 disp("Part (e)");
28 A=80*A/100; // Decreased A
29 Af_dash=A/(1+A*bta); // Decreased Af
30 C=(Af-Af_dash)*100/Af; // Percentage decrease in Af
31 disp(C," Percentage decrease in Af (\%) =");
```

Scilab code Exa 11.7 Upper 3 dB frequency

```
1 // Example 11.7: Low frequency gain, Upper 3 dB frequency
```

```
2 clc, clear
```

```
3 // Without feedback
4 AM=1e4; // Low frequency values of A
5 wH=100; // Upper 3 dB frequency in hertz
6 // With feedback
7 R1=1; // in kilo-ohms
8 R2=9; // in kilo-ohms
9 bta=R1/(R1+R2); // Feedback factor
10 AfM=AM/(1+bta*AM); // Low frequency gain
11 wHf=wH*(1+bta*AM); // Upper 3 dB frequency in hertz
12 wHf=wHf*1e-3; // Upper 3 dB frequency in kilo-hertz
13 disp("For closed loop amplifier :");
14 disp(AfM,"Low frequency gain =");
15 disp(wHf,"Upper 3 dB frequency (kHz) =");
```

Scilab code Exa 11.9 Desensitivity

```
1 // Example 11.9: (a) RE
2 //
                    (b) RL
3 //
                    (c) R1F
4 //
                    (d) Quiescent collector current
5 clc, clear
6 GmF=1; // Transconductance gain in mili-amperes per
      volts
7 AVF=-4; // Voltage gain
8 D=50; // Desensitivity factor
9 RS=1; // in kilo-ohms
10 btao=150;
11 AoL=GmF*D; // Open loop mutual conductance in mili-
     amperes per volts
12
13 disp("Part (a)");
14 RE=(D-1)/AoL; // in kilo-ohms
15 disp(RE, "RE (k) = ");
16
17 disp("Part (b)");
```
```
18 RL=-AVF/GmF; // in kilo-ohms
19 disp(RL,"RL ( k ) =");
20
21 disp("Part (c)");
22 r_pi=btao/AoL-RS-RE; // in kilo-ohms
23 R1F=RS+r_pi+(1+btao)*RE; // in kilo-ohms
24 disp(R1F,"R1F ( k ) =");
25
26 disp("Part (d)");
27 VT=26e-3; // Voltage equivalent to temperatue at
room temperature in volts
28 IC=btao*VT/r_pi; // in mili-amperes
29 disp(IC,"IC (mA) =");
```

Scilab code Exa 11.11 Transfer ratio

```
1 // Example 11.11: (a) Amplifier type
                     (b) Input resistance, Output
2 / /
     resistance, Transfer ratio
3 clc, clear
4 r_pi=1e3; // in ohms
5 gm=0.1; // in mho
6
7 disp("Part (a)");
8 disp("It is a CB-CE cascade, configuration. It has
     low input and high output impedance and hence
     corresponds to a current amplifier.");
9
10 disp("Part (b)");
11 // From low frequency equivalent circuit in Fig.
     11.40
12 btao=gm*r_pi;
13 Rin=r_pi/(1+btao); // Input resistance in ohms
14 Rout=%inf; // Output resistance (= ro of Q2)
15 Ai=gm*gm*Rin*3e3*1e3/(3e3+1e3); // Transfer ratio
```

```
16 disp(Rin,"Input resistance ( ) =");
17 disp(Rout,"Output resistance =");
18 disp(Ai,"Transfer ratio =");
```

Scilab code Exa 11.12 Gain with feedback

```
1 // Example 11.12: (b) AF
2 clc, clear
3 AV=4000;
4 bta=1/300;
5 RS=2; // in kilo-ohms
6 RE=RS; // in kilo-ohms
7 RC=6; // in kilo-ohms
8 btao=200;
9 r_pi=4; // in kilo-ohms
10
11 disp("Part (b)");
12 x=-AV*-btao*RC/(r_pi+RS);
13 AF=x/(1+x*bta);
14 disp(AF,"AF =");
```

Scilab code Exa 11.13 Transfer ratio

```
1 // Example 11.13: (a) Amplifier type
2 // (b) Input resistance, Output
resistance, Transfer ratio
3 clc, clear
4 r_pi=1e3; // in ohms
5 gm=0.1; // in mho
6
7 disp("Part (a)");
8 disp("Q1 is a common collector and Q2 is common
emitter stage. Hence the given circuit is cascade
```

```
of cc and CE stages. As the Rin of a CC is high
     and the Ro of the CE is low, therefore, the given
       circuit approximates a voltage amplifier. If RL
      is chosen a low resistance, the amplifier can be
      considered a voltage-to-current converter.")
9
10 function[c]=parallel(a,b)
       c=a*b/(a+b);
11
12 endfunction
13
14 disp("Part (b)");
15 // From the Fig. 11.42
16 RE1=3e3; // in ohms
17 RC2=0.6e3; // in ohms
18 btao=gm*r_pi;
19 Ri2=r_pi; // in ohms
20 Ri1=r_pi+(1+btao)*parallel(RE1,Ri2); // Input
      resistance in ohms
21 Rout=RC2; // Output resistance (= ro of Q2)
22 AV1=(1+btao)*RE1/(r_pi+(1+btao)*RE1);
23 Ro1=parallel(RE1,r_pi/(1+btao)); // in ohms
24 AV2=-btao*RC2/(Ro1+r_pi);
25 \text{ AV} = \text{AV1} * \text{AV2};
26 Ri1=Ri1*1e-3; // in kilo-ohms
27 Rout=Rout*1e-3; // in kilo-ohms
28 disp(Ri1,"Input resistance (
                                      ) =");
29 disp(Rout,"Output resistance =");
30 disp(AV, "Transfer ratio =");
```

Scilab code Exa 11.15 Small signal gain

```
1 // Example 11.15: Small signal gain, Input
resistance, Output resistance
2 clc, clear
3 btao=100;
```

```
4 r_pi=1e3; // in ohms
5 ICQ=2.5e-3; // in amperes
6 VT=25e-3; // in volts
7 gm=ICQ/VT; // Transconductance in mho
8 r_pi=btao/gm; // Incremental resistance of emitter-
     base diode in ohms
9 // From ac model without feedback in Fig. 11.47
10 RS=10e3; // in ohms
11 RF=47e3; // in ohms
12 RC=4.7e3; // in ohms
13 function[c]=parallel(a,b)
14
      c=a*b/(a+b);
15 endfunction
16 AoL=-gm*parallel(RF,RC)*parallel(RS,parallel(RF,r_pi
     )); // in ohms
17 bta=1/RF;
18 T=-bta*AoL; // Return ratio
19 AF=AoL/(1+T); // in ohms
20 AVF=AF/RS; // Small signal gain
21 RID=parallel(RF,r_pi); // in ohms
22 RID_dash=parallel(RID,RS); // in ohms
23 RIF_dash_I=RID_dash/(1+T); // in ohms
24 RIF_I=RS*RIF_dash_I/(RS-RIF_dash_I); // in ohms
25 RIF_dash_V=RS+RIF_I; // in ohms
26 RoD_dash=parallel(RF,RC); // in ohms
27 RoF_dash=RoD_dash/(1+T); // in ohms
28 RoF=RoF_dash*RC/(RC-RoF_dash); // in ohms
29 disp(RoF);
30 RIF_dash_V=RIF_dash_V*1e-3; // in kilo-ohms
31 RoF=RoF*1e-3; // in kilo-ohms
32 disp(AVF, "Small signal gain =");
33 disp(RIF_dash_V, "Input resistance ( k ) =");
34 disp(RoF, "Output resistance (k ) =");
```

Scilab code Exa 11.16 Closed loop parameters

```
1 // Example 11.16: (a) AF, T
2 / /
                      (b) R1F, RoF
3 clc, clear
4 btao=150;
5 ICQ=1.5e-3; // in amperes
6 VT=25e-3; // Voltage equivalent to temperatue at
      room temperature in volts
7 // From circuit without feedback but with loading in
       Fig. 11.50
8 RS=2e3; // in ohms
9 RE1=0.1e3; // in ohms
10 RF=6.2e3; // in ohms
11 RC1=4.3e3; // in ohms
12 RC2=1.2e3; // in ohms
13 RL=4.7e3; // in ohms
14
15 function[c]=parallel(a,b)
       c=a*b/(a+b);
16
17 endfunction
18
19 disp("Part (a)");
20 gm=ICQ/VT; // Transconductance in mho
21 r_pi=btao/gm; // Incremental resistance of emitter-
      base diode in ohms
22 AV1=-btao*RC1/(RS+r_pi+(1+btao)*parallel(RE1,RF));
23 AV2=-btao*parallel(RC2,parallel(RF+RE1,RL))/(RC1+
      r_pi);
24 \quad AoL = AV1 * AV2;
25 \text{ bta}=-\text{RE1}/(\text{RE1}+\text{RF});
26 T=-bta*AoL;
27 AF = AoL/(1+T);
28 disp(AF, "AF =");
29 disp(T,"T =");
30
31 disp("Part (b)");
32 RID=r_pi+(1+btao)*parallel(RE1,RF); // in ohms
33 RID_dash=RS+RID; // in ohms
34 RIF_dash=RID_dash*(1+T); // in ohms
```

```
35 RIF=RIF_dash-RS; // in ohms
36 RoD=parallel(RC2,RF+RE1); // in ohms
37 RoD_dash=parallel(RoD,RL); // in ohms
38 RoF_dash=RoD_dash/(1+T); // in ohms
39 RoF=RL*RoF_dash/(RL-RoF_dash); // in ohms
40 RIF=RIF*1e-3; // in kilo-ohms
41 disp(RIF,"RIF ( k ) =");
42 disp(RoF,"RoF ( ) =");
```

Scilab code Exa 11.17 Feedback in MOSFETs

```
1 // Example 11.17: (a) T, AoL, AF
2 / /
                       (b) RoF
3 clc, clear
4 gm=1e-3; // in mho
5 rd=20e3; // in ohms
6
7 function[c]=parallel(a,b)
8
       c=a*b/(a+b);
9 endfunction
10
11 disp("Part (a)");
12 // From the ac equivalent circuit in Fig. 11.52
13 RF=10e3; // in ohms
14 RD1=10e3; // in ohms
15 RL=10e3; // in ohms
16 ro=20e3; // in ohms
17 RS=parallel(0.47e3,RF); // in ohms
18 RL2=parallel(ro,parallel(10.47e3,RL)); // in ohms
19 mu=rd*gm; // Amplification factor
20 AV1 = -mu * RD1 / (RD1 + rd + (1 + mu) * RS);
21 AV2 = -gm * RL2;
22 \quad AoL = AV1 * AV2;
23 bta=-0.47/(10+0.47); // Feedback factor
24 T=-bta*AoL;
```

```
25 AF=AoL/(1+T);
26 disp(T,"T =");
27 disp(AoL,"AoL =");
28 disp(AF,"AF =");
29
30 disp("Part (b)");
31 RoD=parallel(ro,10.47e3); // in ohms
32 TSC=0; // for RL=0, T=0
33 ToC=bta*AV1*gm*RoD;
34 // By Blackman's relation
35 RoF=RoD*(1+TSC)/(1+ToC); // in ohms
36 RoF=RoF*1e-3; // in kilo-ohms
37 disp(RoF,"RoF (k) =");
```

Scilab code Exa 11.18 Open and closed loop gain

```
1 // Example 11.18: T, AoL, AF
2 clc, clear
3 function[c]=parallel(a,b)
       c=a*b/(a+b);
4
5 endfunction
6 ICQ1=0.25e-3; // in amperes
7 ICQ2=-0.5e-3; // in amperes
8 bta1=200;
9 VA1=125; // in volts
10 bta2=150;
11 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
12 gm1=ICQ1/VT; // in mho
13 gm2=abs(ICQ2)/VT; // in mho
14 r_pi1=bta1/gm1; // in ohms
15 r_pi2=bta2/gm2; // in ohms
16 ro1=VA1/ICQ1; // in ohms
17 // From ac equivalent circuit in Fig. 11.56
18 RC1=20e3; // in ohms
```

```
19 RS=1e3; // in ohms
20 bta=-0.82/(20+0.82); // Feedback factor
21 RL1=parallel(RC1,ro1); // in ohms
22 Ib2_IC1=RL1/(RL1+r_pi2+(1+bta2)*parallel(20e3,0.82e3
)); // Ib2/IC1
23 Ib1_IS=parallel(RS,20.82e3)/(r_pi1+parallel(RS,20.82
e3)); // Ib1/IS
24 AoL=bta2*Ib2_IC1*bta1*Ib1_IS; // Current gain
without feedback
25 T=-bta*AoL;
26 AF=AoL/(1+T);
27 disp(T,"T =");
28 disp(AoL,"AoL =");
29 disp(AF,"AF =");
```

```
Scilab code Exa 11.19 Closed loop parameters
```

```
1 // Example 11.19: (a) AIF
2 //
                      (b) R1F
3 //
                      (c) A1F'
4 //
                      (d) AVF
5 clc, clear
6 \text{ btao}=50;
7 r_pi=2e3; // in ohms
8 // From equivalent circuit without feedback but
      taking loading effect in Fig. 11.58
9 RS=1e3; // in ohms
10 Rf=15e3; // in ohms
11 RE2=10e3; // in ohms
12 RC1=10e3; // in ohms
13 RC2=10e3; // in ohms
14
15 function[c]=parallel(a,b)
       c=a*b/(a+b);
16
17 endfunction
```

```
18
19 disp("Part (a)");
20 RS_dash=parallel(RS,Rf+RE2); // in ohms
21 gm=btao/r_pi; // in mho
22 RE2_dash=parallel(RE2,Rf); // in ohms
23 Rx=r_pi+(1+btao)*RE2_dash; // in ohms
24 I2_IS=-gm*parallel(RS_dash,r_pi)*RC1/(RC1+Rx); // I2
     /IS
25 AI=-btao*I2_IS; // Open loop
26 If_IS=(1+btao)*I2_IS*RE2/(RE2+Rf); // If/IS
27 bta=If_IS/AI; // Feedback factor
28 T=-bta*AI;
29 AIF = AI / (1+T);
30 disp(AIF, "AIF =");
31
32 disp("Part (b)");
33 RID=parallel(RS,parallel(Rf+RE2,r_pi));
34 R1F=RID/(1+T); // in ohms
35 disp(R1F, "R1F ( ) =");
36
37 disp("Part (c)");
38 Ii_IS=RS/(RS+parallel(Rf+RE2,r_pi)); // Ii'/IS
39 AI_dash=AI*Ii_IS;
40 T=-bta*AI_dash;
41 A1F_dash=AI_dash/(1+T);
42 disp(A1F_dash, "A1F =");
43
44 disp("Part (d)");
45 AVF=AIF*RC2/RS;
46 disp(AVF, "AVF =");
```

#### Scilab code Exa 11.20 Closed loop parameters

```
1 // Example 11.20: (a) AVF
2 // (b) AIF
```

```
(c) RIF
3 //
4 //
                      (d) ROF
5 clc, clear
6 btao=50;
7 r_pi=1.1e3; // in ohms
8 function[c]=parallel(a,b)
9
       c=a*b/(a+b);
10 endfunction
11 // From equivalent circuit of amplifier without
      feedback in Fig. 11.60
12 RS=4.7e3; // in ohms
13 RF=15e3; // in ohms
14 RE2=0.1e3; // in ohms
15 RB1=parallel(91e3,10e3); // in ohms
16 RC1=4.7e3; // in ohms
17 RC2=4.7e3; // in ohms
18 RB2=RB1; // in ohms
19
20 disp("Part (b)");
21 RL1=parallel(RS,parallel(RF+RE2,RB1)); // in ohms
22 I1_IS=RL1/(RL1+r_pi); // I1/IS
23 IC1_IS=btao*I1_IS; // IC1/IS
24 Ri2=r_pi+(1+btao)*parallel(RE2,RF); // in ohms
25 I2_IS=-IC1_IS*parallel(RC1,RB2)/(parallel(RC1,RB2)+
      Ri2); // in ohms
26 IC2_IS=btao*I2_IS; // IC2/IS
27 AID=-IC2_IS/2; // Open loop
28 IF_IS=IC2_IS*RE2/(RE2+RF); // IF/IS
29 bta=IF_IS/AID; // Feedback factor
30 T=-bta*AID;
31 AIF=AID/(1+T);
32 disp(AIF, "AIF =");
33
34 disp("Part (a)");
35 \text{ AVF} = \text{AIF} * \text{RC2}/\text{RS};
36 disp(AVF, "AVF =");
37
38 disp("Part (c)");
```

```
39 RID=parallel(parallel(RS,RE2+RF),parallel(RB1,r_pi))
    ; // in ohms
40 RIF=RID/(1+T); // in ohms
41 disp(RIF,"RIF ( ) =");
42
43 disp("Part (d)");
44 ROF=RC2*1e-3; // in kilo-ohms
45 disp(ROF,"ROF ( k ) =");
```

Scilab code Exa 11.21 Voltage gain

```
1 // Example 11.21: (c) AF, T
2 //
                     (d) Voltage gain
3 clc, clear
4 ICQ1=0.25e-3; // in amperes
5 ICQ2=1e-3; // in amperes
6 ICQ3=0.5e-3; // in amperes
7 RC1=5e3; // in ohms
8 RC2=7.5e3; // in ohms
9 RC3=10e3; // in ohms
10 R1=0.2e3; // in ohms
11 R2=0.33e3; // in ohms
12 RS=0.6e3; // in ohms
13 RF=20e3; // in ohms
14 btao=200;
15 VA=125; // in volts
16 VT=25e-3; // Voltage equivalent to temperatue at
     room temperature in volts
17
18 function[c]=parallel(a,b)
19
       c=a*b/(a+b);
20 endfunction
21
22 disp("Part (c)");
23 gm1=ICQ1/VT; // in mho
```

```
24 r_pi1=btao/gm1; // in ohms
25 ro1=VA/ICQ1; // in ohms
26 gm2=ICQ2/VT; // in mho
27 r_pi2=btao/gm2; // in ohms
28 ro2=VA/ICQ2; // in ohms
29 gm3=ICQ3/VT; // in mho
30 r_pi3=btao/gm3; // in ohms
31 ro3=VA/ICQ3; // in ohms
32 Rin1=r_pi1+(btao+1)*parallel(RF+R2,R1); // in ohms
33 RL1=parallel(RC1,ro1); // in ohms
34 RL2=parallel(RC2,ro2); // in ohms
35 Rin2=r_pi2; // in ohms
36 Rin3=r_pi3+(btao+1)*parallel(R2,RF+R1); // in ohms
37 Io_Ib3=btao; // Io/Ib3
38 Ib3_Ic2=-RL2/(RL2+Rin3); // Ib3/Ic2
39 Ic2_Ib2=btao; // Ic2/Ib2
40 Ib2_Ic1=-RL1/(RL1+Rin2); // Ib2/Ic1
41 Ic1_Ib1=btao; // Ic1/Ib1
42 Ib1_VS=1/(RS+Rin1); // Ib1/VS in mho
43 AoL=Io_Ib3*Ib3_Ic2*Ic2_Ib2*Ib2_Ic1*Ic1_Ib1*Ib1_VS;
     // Open loop
44 bta=-R1*R2/(R1+R2+RF); // Feedback factor
45 T=-bta*AoL;
46 AF = AoL/(1+T);
47 disp(T, "T =");
48 disp(AF, "AF =");
49
50 disp("Part (d)");
51 Vo_VS=-AF*parallel(RC3,ro3);
52 disp(Vo_VS, "Voltage gain =");
```

Scilab code Exa 11.22 Feedback in FETs

```
1 // Example 11.22: AF, RoF
2 clc, clear
```

```
3 gm=2e-3; // in mho
4 rd=20e3; // in ohms
5 RD=12e3; // in ohms
6 RG=500e3; // in ohms
7 Rs=50; // in ohms
8 RF=5e3; // in ohms
9 function[c]=parallel(a,b)
       c=a*b/(a+b);
10
11 endfunction
12 Ro=parallel(RD,rd); // in ohms
13 AV1=-gm*parallel(RD,parallel(rd,RG));
14 AV2=AV1;
15 AV3=-gm*parallel(RD,rd);
16 AV = AV1 * AV2 * AV3;
17 RG_dash=parallel(RG,RF); // in ohms
18 Vi_Vs=RG_dash/(RG_dash+Rs); // Vi/Vs
19 AoL=AV*Vi_Vs*RF/(RF+Ro); // Vo/Vs (Open loop)
20 bta=1/RF; // Feedback factor
21 RM=AoL*Rs; // in ohms
22 T=-bta*RM; // Return ratio
23 AF = AoL / (1+T);
24 RoD=parallel(Ro,RF); // in ohms
25 RoF=RoD/(1+T); // in ohms
26 disp(AF, "AF =");
27 disp(RoF, "RoF ( ) =");
```

### Chapter 12

## Oscillators

Scilab code Exa 12.1 Phase shift oscillator

```
1 // Example 12.1: (a) RD
2 //
                    (b) Product RC
                    (c) Reasonable value of R and C
3 //
4 clc, clear
5 fo=8e3; // in hertz
6 mu = 59;
7 rd=10; // in kilo-ohms
8
9 disp("Part (a)");
10 RD=29*rd/(mu-29); // in kilo-ohms
11 disp(RD,"RD ( k ) =");
12
13 disp("Part (b)");
14 RC=1/(2*%pi*fo*sqrt(6)); // in seconds
15 RC=RC*1e6; // in micro-seconds
16 disp(RC, "Product RC ( s ) =");
17
18 disp("Part (c)");
19 R=50; // in kilo-ohms
20 C=RC/R; // in nano-farad
21 C=C*1e3; // in pico-farad
```

```
22 disp(R, "Reasonable value of R ( k ) =");
23 disp(C, "Reasonable value of C (pF) =");
```

Scilab code Exa 12.2 Wien Bridge oscillator

```
1 // Example 12.2: Designing a Wein Bridge Oscillator
2 clc, clear
3 fo=2e3; // in hertz
4 R=10; // in kilo-ohms
5 C=1/(2*%pi*fo*R*1e3); // in farads
6 C=C*1e9; // in nano-farads
7 disp(R,"R1 ( k
                    ) =");
8 disp(R,"R2 ( k
                    ) =");
9 disp(2*R,"R3 ( k
                     ) =");
10 disp(R,"R4 ( k
                   ) =");
11 disp(C, "C1 (nF) =");
12 disp(C,"C2 (nF) =");
```

#### Scilab code Exa 12.3 Hartley oscillator

```
1 // Example 12.3: Range of capacitance
2 clc, clear
3 L1=2e-3; // in henry
4 L2=1.5e-3; // in henry
5 fmin=1000e3; // in hertz
6 fmax=2000e3; // in hertz
7 Cmin=1/((2*%pi*fmax)^2*(L1+L2)); // in farads
8 Cmax=1/((2*%pi*fmin)^2*(L1+L2)); // in farads
9 Cmin=Cmin*1e12; // in pico-farads
10 Cmax=Cmax*1e12; // in pico-farads
11 disp(Cmin,"Minimum value of C (pF) =");
12 disp(Cmax,"Maximum value of C (pF) =");
```

### Chapter 13

# Power Amplifiers and Voltage Regulators

Scilab code Exa 13.1 Series fed amplifier

```
1 // Example 13.1: dc input power, ac output power,
     Efficiency
2 clc, clear
3 Ib=5e-3; // Base current in amperes
4 // From Fig. 13.8
5 RB=1.5e3; // in ohms
6 RC=16; // in ohms
7 bta=40;
8 VCC=18; // in volts
9 VBE=0.7; // in volts
10 IBQ=(VCC-VBE)/RB; // in amperes
11 ICQ=bta*IBQ; // in amperes
12 Pi_dc=VCC*ICQ; // dc input power in watts
13 Ic=bta*Ib; // in amperes
14 Po_ac=Ic^2*RC; // ac output power
15 eta=Po_ac*100/Pi_dc; // Efficiency in percentage
16 disp(Pi_dc,"dc input power (W) =");
17 disp(Po_ac," ac output power (W) =");
18 disp(eta, "Efficiency (%) =");
```

Scilab code Exa 13.2 Transformer turn ratio

```
1 // Example 13.2: Transformer turns ratio
2 clc, clear
3 function[c]=parallel(a,b)
4      c=a*b/(a+b);
5 endfunction
6 RL=parallel(parallel(16,16),parallel(16,16)); // in
      ohms
7 RL_dash=8e3; // in ohms
8 TR=sqrt(RL_dash/RL); // Transformer turns ratio
9 disp(TR,"Transformer turns ratio =");
```

Scilab code Exa 13.3 Class A amplifier

```
1 // Example 12.3: Efficiency
2 clc, clear
3 P_ac=2; // in watts
4 ICQ=150e-3; // in amperes
5 VCC=36; // in volts
6 P_dc=VCC*ICQ; // in watts
7 eta=P_ac*100/P_dc; // Efficiency in percentage
8 disp(eta," Efficiency (%) =");
```

Scilab code Exa 13.4 Class B push pull amplifier

1 // Example 13.4: Maximum input power, Maximum ac output power, Maximum conversion efficiency, Maximum power dissipated by each transistor

```
2 clc, clear
3 VCC=15; // in volts
4 RL=8; // in ohms
5 P_dc=2*VCC^2/(%pi*RL); // Maximum input power in
     watts
6 P_ac=VCC^2/(2*RL); // Maximum ac output power in
     watts
7 eta=P_ac*100/P_dc; // Maximum efficiency in
     percentage
8 PD=2*VCC^2/(%pi^2*RL); // Maximum power dissipated
     in watts
9 PD_each=PD/2; // Maximum power dissipated by each
     transistor in watts
10 disp(P_dc, "Maximum input power (W) =");
11 disp(P_ac, "Maximum ac output power (W) =");
12 disp(eta, "Maximum conversion efficiency (\%) =");
13 disp(PD_each," Maximum power dissipated by each
```

```
transistor (W) = ");
```

#### Scilab code Exa 13.5 Class B output stage

```
1 // Example 13.5: Supply voltage, Peak current drawn
from each supply, Total supply power, Power
conversion efficiency, Maximum power that each
transistor can dissipate safely
```

```
2 clc, clear
```

```
3 P_ac=20; // Average power delivered in watts
```

```
4 RL=8; // Load in ohms
```

```
5 Vm=sqrt(2*P_ac*RL); // Peak output voltage in volts
```

- 6 VCC=Vm+5; // Supply voltage in volts
- 7 Im=Vm/RL; // Peak current drawn from each supply in amperes
- 8 P\_dc=2\*Im\*VCC/%pi; // Total supply power in watts

Scilab code Exa 13.6 Thermal considerations

```
1 // Example 13.6: Thermal resistance, Power rating at
      70 C, Junction temperature at 100 mW
2 clc, clear
3 TAo=25; // in
                  С
4 PDo=200; // in mili-watts
5 Tj_max=150; // Maximum junction temperature in
                                                  C
6 T=70; // in C
7 P=100; // in mili-watts
8 TA=50; // Ambient temperature in C
9 theta=(Tj_max-TAo)/PDo; // Thermal resistance in
                                                     С
      per mili-watts
10 PR=(Tj_max-T)/theta; // Power rating at 70 C in
     mili-watts
11 Tj=TA+theta*P; // Junction temperature at 100 mW in
      С
12 disp(theta, "Thermal resistance (C/mW) =");
13 disp(PR, "Power rating at 70 C (mW) =");
14 disp(Tj, "Junction temperature at 100 mW ( C ) =");
```